

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

- Qualified for Automotive Applications
- ESD Protection Exceeds 1000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Supply Current . . . 300 μ A Max
- High Unity-Gain Bandwidth . . . 2 MHz Typ
- High Slew Rate . . . 0.45 V/ μ s Min
- Supply-Current Change Over Full Temp Range . . . 10 μ A Typ at $V_{CC} \pm \pm 15$ V
- Specified for Both 5-V Single-Supply and ± 15 -V Operation
- Phase-Reversal Protection
- High Open-Loop Gain . . . 6.5 V/ μ V (136 dB) Typ
- Low Offset Voltage . . . 100 μ V Max
- Offset Voltage Drift With Time 0.005 μ V/mo Typ
- Low Input Bias Current . . . 50 nA Max
- Low Noise Voltage . . . 19 nV/ $\sqrt{\text{Hz}}$ Typ

description

The TLE202x and TLE202xA devices are precision, high-speed, low-power operational amplifiers using a new Texas Instruments Excalibur process. These devices combine the best features of the OP21 with highly improved slew rate and unity-gain bandwidth.

The complementary bipolar Excalibur process utilizes isolated vertical pnp transistors that yield dramatic improvement in unity-gain bandwidth and slew rate over similar devices.

The addition of a bias circuit in conjunction with this process results in extremely stable parameters with both time and temperature. This means that a precision device remains a precision device even with changes in temperature and over years of use.

This combination of excellent dc performance with a common-mode input voltage range that includes the negative rail makes these devices the ideal choice for low-level signal conditioning applications in either single-supply or split-supply configurations. In addition, these devices offer phase-reversal protection circuitry that eliminates an unexpected change in output states when one of the inputs goes below the negative supply rail.

A variety of available options includes small-outline versions for high-density systems applications.

The Q-suffix devices are characterized for operation over the full automotive temperature range of -40°C to 125°C .



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS
INSTRUMENTS**

POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

Copyright © 2008, Texas Instruments Incorporated

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

ORDERING INFORMATION†

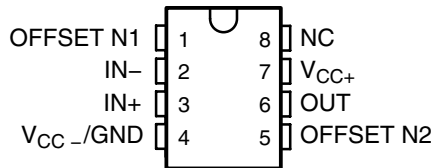
T _A	V _{IO} max AT 25°C	PACKAGE‡		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 125°C	200 µV	SOIC (D)	Tape and reel	TLE2021AQDRQ1	2021AQ
		TSSOP (PW)	Tape and reel	TLE2021AQPWRQ1§	2021AQ
	500 µV	SOIC (D)	Tape and reel	TLE2021QDRQ1	2021Q1
		TSSOP (PW)	Tape and reel	TLE2021QPWRQ1§	2021Q1
-40°C to 125°C	300 µV	SOIC (D)	Tape and reel	TLE2022AQDRQ1	2021AQ
		TSSOP (PW)	Tape and reel	TLE2022AQPWRQ1§	2022AQ1
	500 µV	SOIC (D)	Tape and reel	TLE2022QDRQ1	2022Q1
		TSSOP (PW)	Tape and reel	TLE2022QPWRQ1§	2022Q1
-40°C to 125°C	750 µV	SOP (DW)	Tape and reel	TLE2024AQDWRQ1	2024AQ1
	1000 µV	SOP (DW)	Tape and reel	TLE2024QDWRQ1	2024Q1

† For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at <http://www.ti.com>.

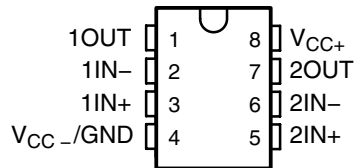
‡ Package drawings, thermal data, and symbolization are available at <http://www.ti.com/packaging>.

§ Product preview

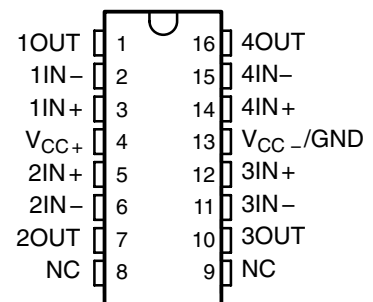
TLE2021
D OR PW PACKAGE
(TOP VIEW)



TLE2022
D OR PW PACKAGE
(TOP VIEW)



TLE2024
DW PACKAGE
(TOP VIEW)

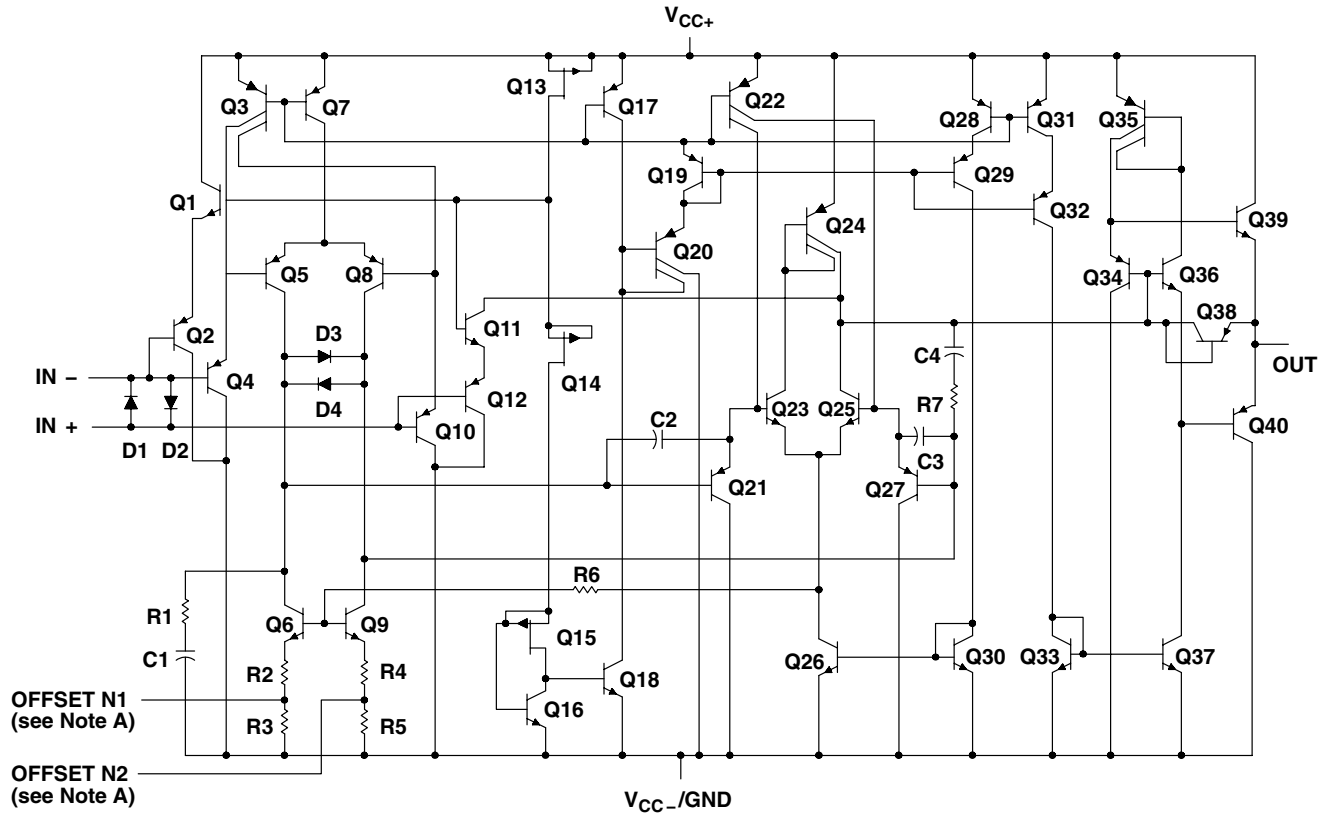


NC – No internal connection

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

equivalent schematic (each amplifier)



ACTUAL DEVICE COMPONENT COUNT			
COMPONENT	TLE2021	TLE2022	TLE2024
Transistors	40	80	160
Resistors	7	14	28
Diodes	4	8	16
Capacitors	4	8	16

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{CC+} (see Note 1)	20 V
Supply voltage, V_{CC-} (see Note 1)	-20 V
Differential input voltage, V_{ID} (see Note 2)	± 0.6 V
Input voltage range, V_I (any input, see Note 1)	$\pm V_{CC}$
Input current, I_I (each input)	± 1 mA
Output current, I_O (each output):	
TLE2021	± 20 mA
TLE2022	± 30 mA
TLE2024	± 40 mA
Total current into V_{CC+}	80 mA
Total current out of V_{CC-}	80 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Operating free-air temperature range, T_A : Q suffix	-40°C to 125°C
Operating virtual junction temperature, T_J	150°C
Package thermal impedance, $R_{\theta JA}$ (see Notes 4 and 5):	
D (8 pin)	97°C/W
DW (16 pin)	57°C/W
PW (8 pin)	149°C/W
PW (14 pin)	113°C/W
Storage temperature range, T_{stg}	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 3 seconds: D or PW package	300°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
- All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
 - Differential voltages are at $IN+$ with respect to $IN-$. Excessive current flows if a differential input voltage in excess of approximately ± 600 mV is applied between the inputs unless some limiting resistance is used.
 - The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.
 - Maximum power dissipation is a function of $T_J(\max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\max) - T_A)/\theta_{JA}$. Selecting the maximum of 150°C can affect reliability.
 - The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V_{CC}		± 2	± 20	V
Common-mode input voltage, V_{IC}	$V_{CC} = \pm 5$ V	0	3.2	V
	$V_{CC\pm} = \pm 15$ V	-15	13.2	
Operating free-air temperature, T_A		-40	125	°C



TLE202x-Q1, TLE202xA-Q1
EXCALIBUR HIGH-SPEED LOW-POWER PRECISION
OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TLE2021 electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2021-Q1			TLE2021A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	120		600	100		400	μV
		Full range	800			550			
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range	2			2			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C	0.005			0.005			$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C	0.2		6	0.2		6	nA
		Full range	10			10			
I_{IB} Input bias current	25°C	25		70	25		70	nA	
	Full range	90			90				
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3.5	-0.3 to 4	0 to 3.5	-0.3 to 4	V		
		Full range	0 to 3.2		0 to 3.2				
V_{OH} High-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4	4.3		4	4.3		V
		Full range	3.8			3.8			
V_{OL} Low-level output voltage		25°C	0.7		0.8	0.7		0.8	V
		Full range	0.95			0.95			
A_{VD} Large-signal differential voltage amplification	$V_O = 1.4\text{ V to }4\text{ V}, R_L = 10\ \text{k}\Omega$	25°C	0.3	1.5		0.3	1.5		$\text{V}/\mu\text{V}$
		Full range	0.1			0.1			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50\ \Omega$	25°C	85	110		85	110		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC} = 5\text{ V to }30\text{ V}$	25°C	105	120		105	120		dB
		Full range	100			100			
I_{CC} Supply current	$V_O = 2.5\text{ V}, \text{ No load}$	25°C	170		300	170		300	μA
		Full range	300			300			
ΔI_{CC} Supply current change over operating temperature range		Full range	9			9			μA

† Full range is -40°C to 125°C .

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.



TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TLE2021 electrical characteristics at specified free-air temperature, $V_{CC} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2021-Q1			TLE2021A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0,$ $R_S = 50 \Omega$	25°C	120	500		80	300	μV	
		Full range		700		450			
α_{VIO} Temperature coefficient of input offset voltage		Full range	2			2		$\mu V/^\circ C$	
Input offset voltage long-term drift (see Note 4)		25°C	0.006			0.006		$\mu V/mo$	
I_{IO} Input offset current		25°C	0.2	6		0.2	6	nA	
		Full range		10		10			
I_{IB} Input bias current	25°C	25	70		25	70	nA		
	Full range		90		90				
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	-15 to 13.5	-15.3 to 14		-15 to 13.5	-15.3 to 14	V	
		Full range	-15 to 13.2			-15 to 13.2			
V_{OM+} Maximum positive peak output voltage swing	$R_L = 10 k\Omega$	25°C	14	14.3		14	14.3	V	
		Full range	13.8			13.8			
V_{OM-} Maximum negative peak output voltage swing		25°C	-13.7	-14.1		-13.7	-14.1	V	
		Full range	-13.6			-13.6			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 10 k\Omega$	25°C	1	6.5		1	6.5	V/ μV	
		Full range	0.5			0.5			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $R_S = 50 \Omega$	25°C	100	115		100	115	dB	
		Full range	96			96			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V	25°C	105	120		105	120	dB	
		Full range	100			100			
I_{CC} Supply current	$V_O = 0,$ No load	25°C	200	350		200	350	μA	
		Full range		350		350			
ΔI_{CC} Supply current change over operating temperature range		Full range		10		10		μA	

† Full range is $-40^\circ C$ to $125^\circ C$.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at $T_A = 150^\circ C$ extrapolated to $T_A = 25^\circ C$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.



TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TLE2022 electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2022-Q1			TLE2022A-Q1			UNIT		
			MIN	TYP	MAX	MIN	TYP	MAX			
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	600			400			μV		
		Full range	800			550					
α_{VIO} Temperature coefficient of input offset voltage		Full range	2			2			$\mu\text{V}/^\circ\text{C}$		
Input offset voltage long-term drift (see Note 4)		25°C	0.005			0.005			$\mu\text{V}/\text{mo}$		
I_{IO} Input offset current		25°C	0.5	6		0.4	6		nA		
		Full range	10			10					
I_{IB} Input bias current		25°C	35	70		33	70		nA		
		Full range	90			90					
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3.5	-0.3 to 4	0 to 3.5	-0.3 to 4		V			
		Full range	0 to 3.2		0 to 3.2						
V_{OH} High-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4	4.3		4	4.3		V		
		Full range	3.8			3.8					
V_{OL} Low-level output voltage		25°C	0.7		0.8	0.7		0.8	V		
		Full range	0.95			0.95					
A_{VD} Large-signal differential voltage amplification	$V_O = 1.4\text{ V to }4\text{ V}, R_L = 10\ \text{k}\Omega$	25°C	0.3	1.5		0.4	1.5		$\text{V}/\mu\text{V}$		
		Full range	0.1			0.1					
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50\ \Omega$	25°C	85	100		87	102		dB		
		Full range	80			82					
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC} = 5\text{ V to }30\text{ V}$	25°C	100	115		103	118		dB		
		Full range	95			98					
I_{CC} Supply current	$V_O = 2.5\text{ V}, \text{ No load}$	25°C	450		600		450		600		μA
		Full range	600			600					
ΔI_{CC} Supply current change over operating temperature range		Full range	37			37			μA		

† Full range is -40°C to 125°C .

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TLE2022 electrical characteristics at specified free-air temperature, $V_{CC} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2022-Q1			TLE2022A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50 \Omega$	25°C	150	500		120	300	μV	
		Full range		700		450			
αV_{IO} Temperature coefficient of input offset voltage		Full range	2			2		$\mu V/^\circ C$	
Input offset voltage long-term drift (see Note 4)		25°C	0.006			0.006		$\mu V/mo$	
I_{IO} Input offset current		25°C	0.5	6		0.4	6	nA	
		Full range		10		10			
I_{IB} Input bias current	25°C	35	70		33	70	nA		
	Full range		90		90				
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	-15 to 13.5	-15.3 to 14		-15 to 13.5	-15.3 to 14	V	
		Full range	-15 to 13.2			-15 to 13.2			
V_{OM+} Maximum positive peak output voltage swing	$R_L = 10 k\Omega$	25°C	14	14.3		14	14.3	V	
		Full range	13.8			13.8			
V_{OM-} Maximum negative peak output voltage swing		25°C	-13.7	-14.1		-13.7	-14.1	V	
		Full range	-13.6			-13.6			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 10 k\Omega$	25°C	0.8	4		1	7	V/ μV	
		Full range	0.8			1			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50 \Omega$	25°C	95	106		97	109	dB	
		Full range	91			93			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V	25°C	100	115		103	118	dB	
		Full range	95			98			
I_{CC} Supply current	$V_O = 0, \text{ No load}$	25°C		550	700		550	700	μA
		Full range		700		700			
ΔI_{CC} Supply current change over operating temperature range		Full range		60			60		μA

† Full range is $-40^\circ C$ to $125^\circ C$.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at $T_A = 150^\circ C$ extrapolated to $T_A = 25^\circ C$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.



TLE202x-Q1, TLE202xA-Q1
EXCALIBUR HIGH-SPEED LOW-POWER PRECISION
OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TLE2024 electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2024-Q1			TLE2024A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega$	25°C	1100			850			μV
		Full range	1300			1050			
α_{VIO} Temperature coefficient of input offset voltage		Full range	2			2			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C	0.005			0.005			$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C	0.6	6	0.5	6	nA		
		Full range	10			10			
I_{IB} Input bias current		25°C	45	70	40	70	nA		
		Full range	90			90			
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3.5	-0.3 to 4	0 to 3.5	-0.3 to 4	V		
		Full range	0 to 3.2		0 to 3.2				
V_{OH} High-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	3.9	4.2	3.9	4.2	V		
		Full range	3.7			3.7			
V_{OL} Low-level output voltage		25°C	0.7	0.8	0.7	0.8	V		
		Full range	0.95			0.95			
A_{VD} Large-signal differential voltage amplification	$V_O = 1.4\text{ V to }4\text{ V}, R_L = 10\ \text{k}\Omega$	25°C	0.2	1.5	0.3	1.5	$\text{V}/\mu\text{V}$		
		Full range	0.1			0.1			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50\ \Omega$	25°C	80	90	82	92	dB		
		Full range	80			82			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$	25°C	98	112	100	115	dB		
		Full range	93			95			
I_{CC} Supply current	$V_O = 0, \text{ No load}$	25°C	800	1200	800	1200	μA		
		Full range	1200			1200			
ΔI_{CC} Supply current change over operating temperature range		Full range	50			50			μA

† Full range is -40°C to 125°C .

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TLE2024 electrical characteristics at specified free-air temperature, $V_{CC} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2024-Q1			TLE2024A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50 \Omega$	25°C	1000			750			μV
		Full range	1200			950			
α_{VIO} Temperature coefficient of input offset voltage		Full range	2			2			$\mu V/^\circ C$
Input offset voltage long-term drift (see Note 4)		25°C	0.006			0.006			$\mu V/mo$
I_{IO} Input offset current		25°C	0.6	6		0.2	6	nA	
		Full range	10			10			
I_{IB} Input bias current	25°C	50	70		45	70	nA		
	Full range	90			90				
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	-15 to 13.5	-15.3 to 14		-15 to 13.5	-15.3 to 14	V	
		Full range	-15 to 13.2			-15 to 13.2			
V_{OM+} Maximum positive peak output voltage swing	$R_L = 10 k\Omega$	25°C	13.8	14.1		13.8	14.2	V	
		Full range	13.7			13.7			
V_{OM-} Maximum negative peak output voltage swing		25°C	-13.7	-14.1		-13.7	-14.1	V	
		Full range	-13.6			-13.6			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 10 k\Omega$	25°C	0.4	2		0.8	4	V/ μV	
		Full range	0.4			0.8			
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50 \Omega$	25°C	92	102		94	105	dB	
		Full range	88			90			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V	25°C	98	112		100	115	dB	
		Full range	93			95			
I_{CC} Supply current	$V_O = 0, \text{ No load}$	25°C	1050	1400		1050	1400	μA	
		Full range	1400			1400			
ΔI_{CC} Supply current change over operating temperature range		Full range	85			85			μA

† Full range is $-40^\circ C$ to $125^\circ C$.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at $T_A = 150^\circ C$ extrapolated to $T_A = 25^\circ C$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.



TLE202x-Q1, TLE202xA-Q1
EXCALIBUR HIGH-SPEED LOW-POWER PRECISION
OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TLE2021 operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	T_A	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_O = 1\text{ V to }3\text{ V}$, See Figure 1	25°C		0.5		$\text{V}/\mu\text{s}$
V_n	Equivalent input noise voltage (see Figure 2)	$f = 10\text{ Hz}$	25°C		21		nV/Hz
		$f = 1\text{ kHz}$	25°C		17		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\text{ Hz}$	25°C		0.16		μV
		$f = 0.1\text{ to }10\text{ Hz}$	25°C		0.47		
I_n	Equivalent input noise current		25°C		0.9		pA/Hz
B_1	Unity-gain bandwidth	See Figure 3	25°C		1.2		MHz
ϕ_m	Phase margin at unity gain	See Figure 3	25°C		42°		

TLE2021 operating characteristics at specified free-air temperature, $V_{CC} = \pm 15\text{ V}$

PARAMETER		TEST CONDITIONS	T_A^\dagger	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_O = \pm 10\text{ V}$, See Figure 1	25°C	0.45	0.65		$\text{V}/\mu\text{s}$
			Full range	0.4			
V_n	Equivalent input noise voltage (see Figure 2)		$f = 10\text{ Hz}$	25°C	19		nV/Hz
			$f = 1\text{ kHz}$	25°C	15		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		$f = 0.1\text{ to }1\text{ Hz}$	25°C	0.16		μV
			$f = 0.1\text{ to }10\text{ Hz}$	25°C	0.47		
I_n	Equivalent input noise current		25°C		0.09		pA/Hz
B_1	Unity-gain bandwidth	See Figure 3	25°C		2		MHz
ϕ_m	Phase margin at unity gain	See Figure 3	25°C		46°		

† Full range is -40°C to 125°C for the Q-suffix devices.

TLE2022 operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_O = 1\text{ V to }3\text{ V}$, See Figure 1		0.5		$\text{V}/\mu\text{s}$
V_n	Equivalent input noise voltage (see Figure 2)	$f = 10\text{ Hz}$		21		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		17		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\text{ Hz}$		0.16		μV
		$f = 0.1\text{ to }10\text{ Hz}$		0.47		
I_n	Equivalent input noise current			0.1		$\text{pA}/\sqrt{\text{Hz}}$
B_1	Unity-gain bandwidth	See Figure 3		1.7		MHz
ϕ_m	Phase margin at unity gain	See Figure 3		47°		

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TLE2022 operating characteristics at specified free-air temperature, $V_{CC} = \pm 15\text{ V}$

PARAMETER		TEST CONDITIONS	T_A^\dagger	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_O = \pm 10\text{ V}$, See Figure 1	25°C	0.45	0.65		$\text{V}/\mu\text{s}$
			Full range	0.4			
V_n	Equivalent input noise voltage (see Figure 2)	$f = 10\text{ Hz}$	25°C		19		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$	25°C		15		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\text{ Hz}$	25°C		0.16		μV
		$f = 0.1\text{ to }10\text{ Hz}$	25°C		0.47		
I_n	Equivalent input noise current		25°C		0.1		$\text{pA}/\sqrt{\text{Hz}}$
B_1	Unity-gain bandwidth	See Figure 3	25°C		2.8		MHz
ϕ_m	Phase margin at unity gain	See Figure 3	25°C		52°		

† Full range is -40°C to 125°C .

TLE2024 operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_O = 1\text{ V to }3\text{ V}$, See Figure 1		0.5		$\text{V}/\mu\text{s}$
V_n	Equivalent input noise voltage (see Figure 2)	$f = 10\text{ Hz}$		21		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		17		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\text{ Hz}$		0.16		μV
		$f = 0.1\text{ to }10\text{ Hz}$		0.47		
I_n	Equivalent input noise current			0.1		$\text{pA}/\sqrt{\text{Hz}}$
B_1	Unity-gain bandwidth	See Figure 3		1.7		MHz
ϕ_m	Phase margin at unity gain	See Figure 3		47°		

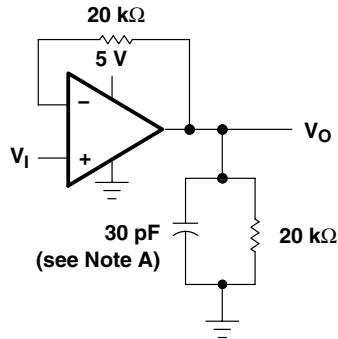
TLE2024 operating characteristics at specified free-air temperature, $V_{CC} = \pm 15\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T_A^\dagger	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_O = \pm 10\text{ V}$, See Figure 1	25°C	0.45	0.7		$\text{V}/\mu\text{s}$
			Full range	0.4			
V_n	Equivalent input noise voltage (see Figure 2)	$f = 10\text{ Hz}$	25°C		19		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$	25°C		15		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ to }1\text{ Hz}$	25°C		0.16		μV
		$f = 0.1\text{ to }10\text{ Hz}$	25°C		0.47		
I_n	Equivalent input noise current		25°C		0.1		$\text{pA}/\sqrt{\text{Hz}}$
B_1	Unity-gain bandwidth	See Figure 3	25°C		2.8		MHz
ϕ_m	Phase margin at unity gain	See Figure 3	25°C		52°		

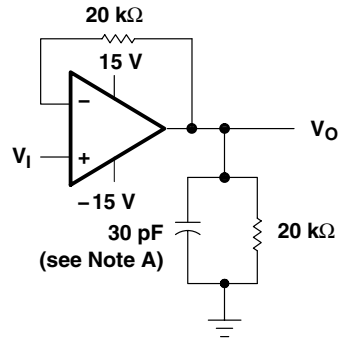
† Full range is -40°C to 125°C .



PARAMETER MEASUREMENT INFORMATION



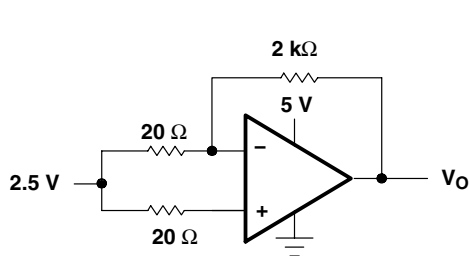
(a) SINGLE SUPPLY



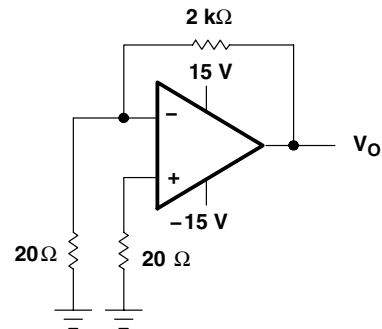
(b) SPLIT SUPPLY

NOTE A: C_L includes fixture capacitance.

Figure 1. Slew-Rate Test Circuit

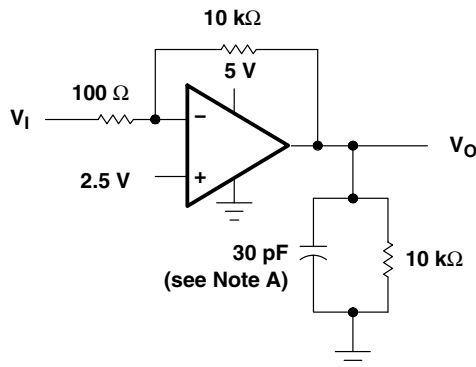


(a) SINGLE SUPPLY

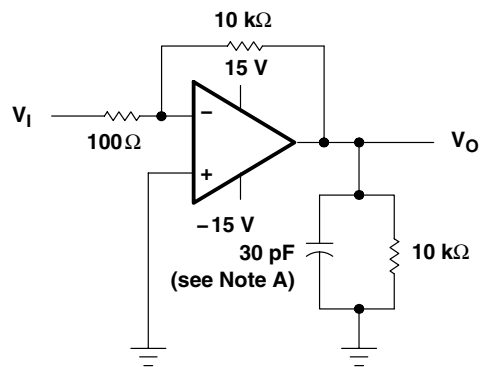


(b) SPLIT SUPPLY

Figure 2. Noise-Voltage Test Circuit



(a) SINGLE SUPPLY



(b) SPLIT SUPPLY

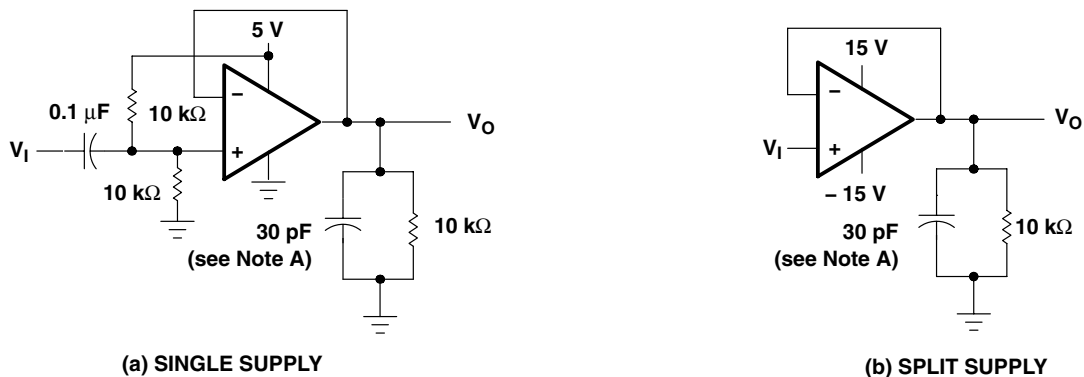
NOTE A: C_L includes fixture capacitance.

Figure 3. Unity-Gain Bandwidth and Phase-Margin Test Circuit

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

PARAMETER MEASUREMENT INFORMATION



NOTE A: C_L includes fixture capacitance.

Figure 4. Small-Signal Pulse-Response Test Circuit

typical values

Typical values presented in this data sheet represent the median (50% point) of device parametric performance.

TLE202x-Q1, TLE202xA-Q1
EXCALIBUR HIGH-SPEED LOW-POWER PRECISION
OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

Table of Graphs

		FIGURE	
V_{IO}	Input offset voltage	Distribution	5, 6, 7
I_{IB}	Input bias current	vs Common-mode input voltage vs Free-air temperature	8, 9, 10 11, 12, 13
I_I	Input current	vs Differential input voltage	14
V_{OM}	Maximum peak output voltage	vs Output current vs Free-air temperature	15, 16, 17 18
V_{OH}	High-level output voltage	vs High-level output current vs Free-air temperature	19, 20 21
V_{OL}	Low-level output voltage	vs Low-level output current vs Free-air temperature	22 23
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	24, 25
A_{VD}	Large-signal differential voltage amplification	vs Frequency vs Free-air temperature	26 27, 28, 29
I_{OS}	Short-circuit output current	vs Supply voltage vs Free-air temperature	30 – 33 34 – 37
I_{CC}	Supply current	vs Supply voltage vs Free-air temperature	38, 39, 40 41, 42, 43
CMRR	Common-mode rejection ratio	vs Frequency	44, 45, 46
SR	Slew rate	vs Free-air temperature	47, 48, 49
	Voltage-follower small-signal pulse response		50, 51
	Voltage-follower large-signal pulse response		52 – 57
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	0.1 to 1 Hz 0.1 to 10 Hz	58 59
V_n	Equivalent input noise voltage	vs Frequency	60
B_1	Unity-gain bandwidth	vs Supply voltage vs Free-air temperature	61, 62 63, 64
ϕ_m	Phase margin	vs Supply voltage vs Load capacitance vs Free-air temperature	65, 66 67, 68 69, 70
	Phase shift	vs Frequency	26

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

**DISTRIBUTION OF TLE2021
INPUT OFFSET VOLTAGE**

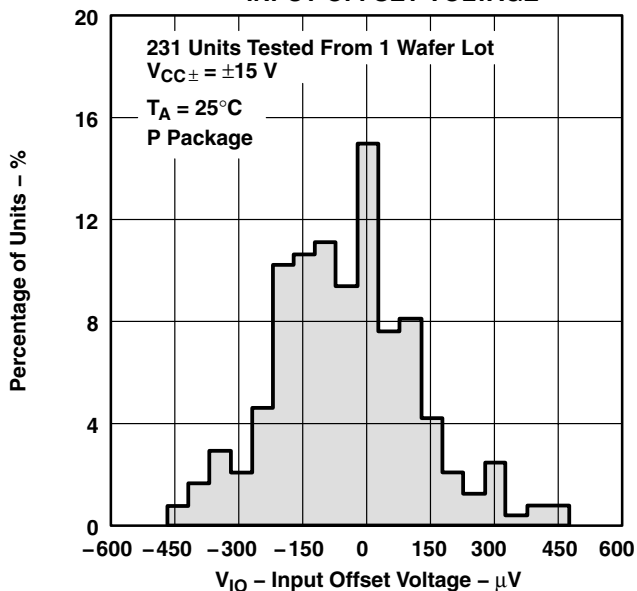


Figure 5

**DISTRIBUTION OF TLE2022
INPUT OFFSET VOLTAGE**

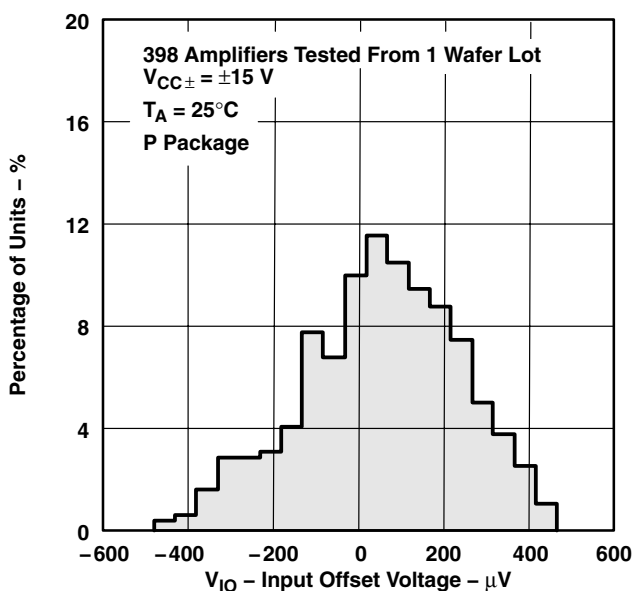


Figure 6

**DISTRIBUTION OF TLE2024
INPUT OFFSET VOLTAGE**

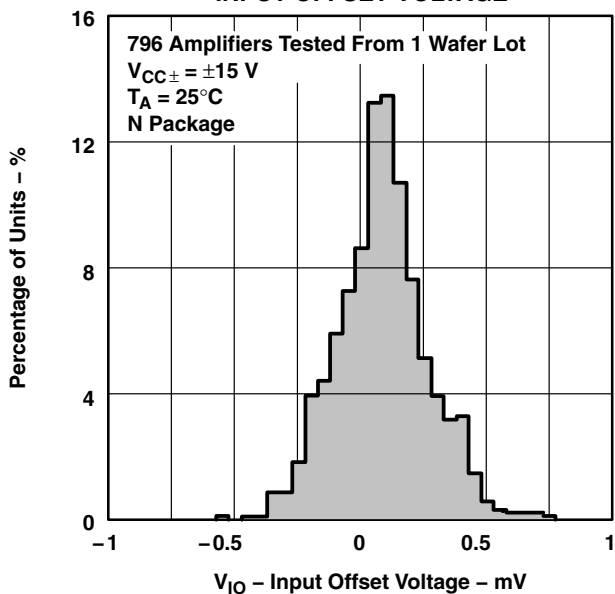


Figure 7

**TLE2021
INPUT BIAS CURRENT
vs
COMMON-MODE INPUT VOLTAGE**

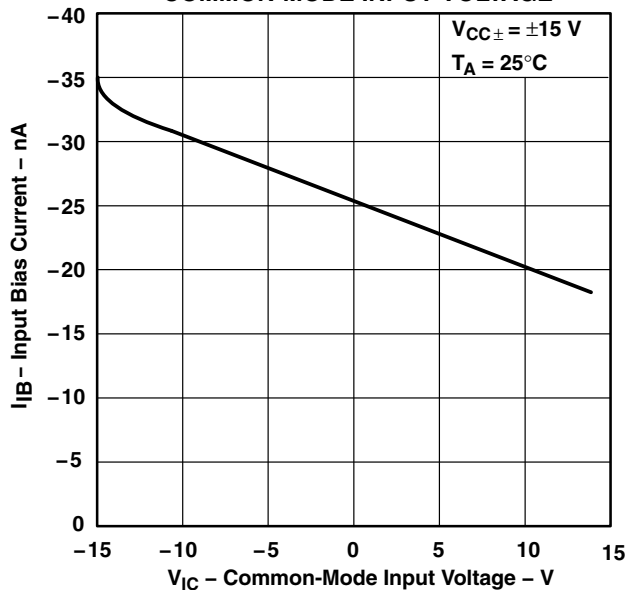
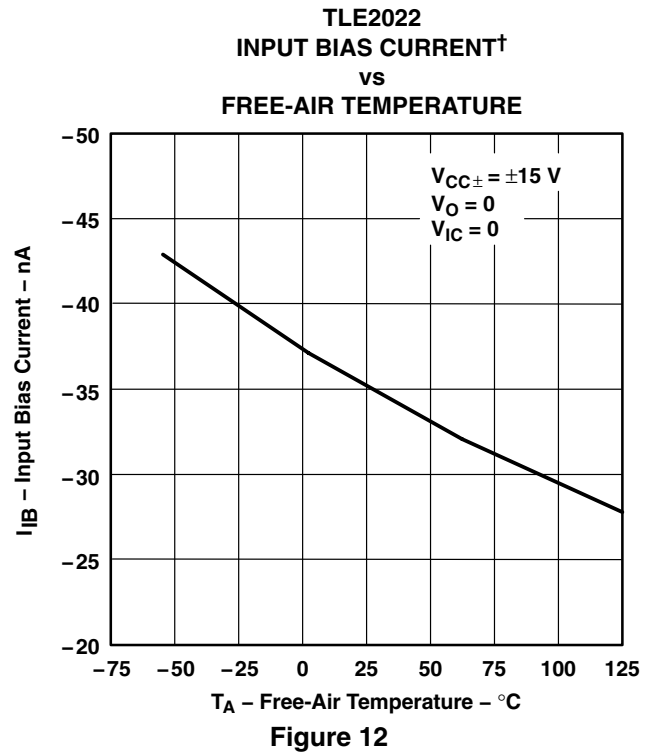
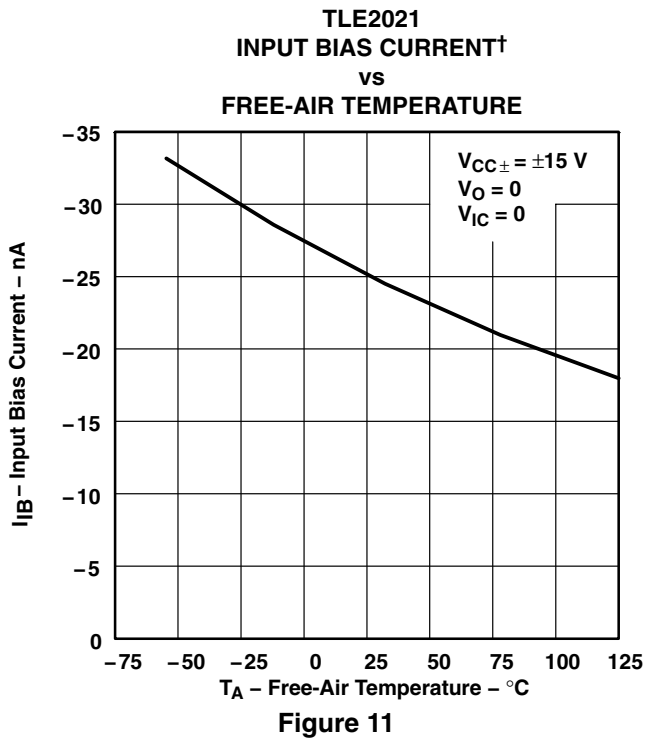
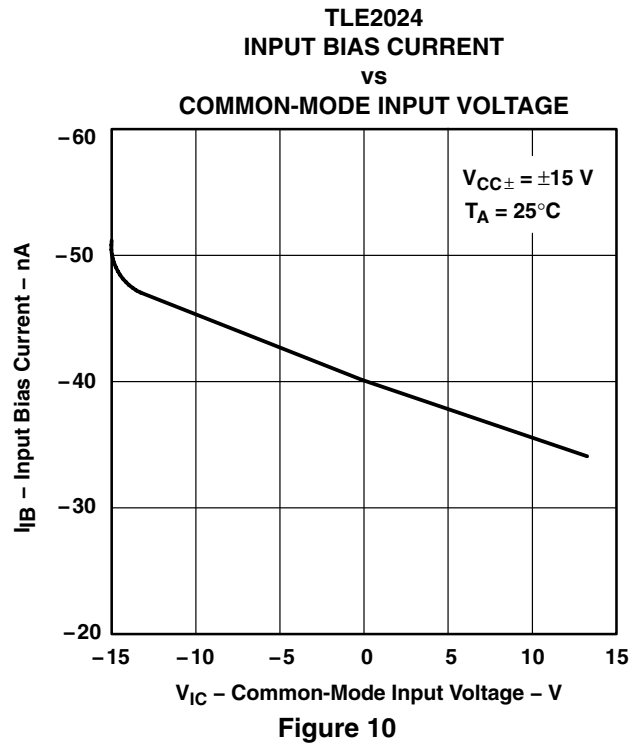
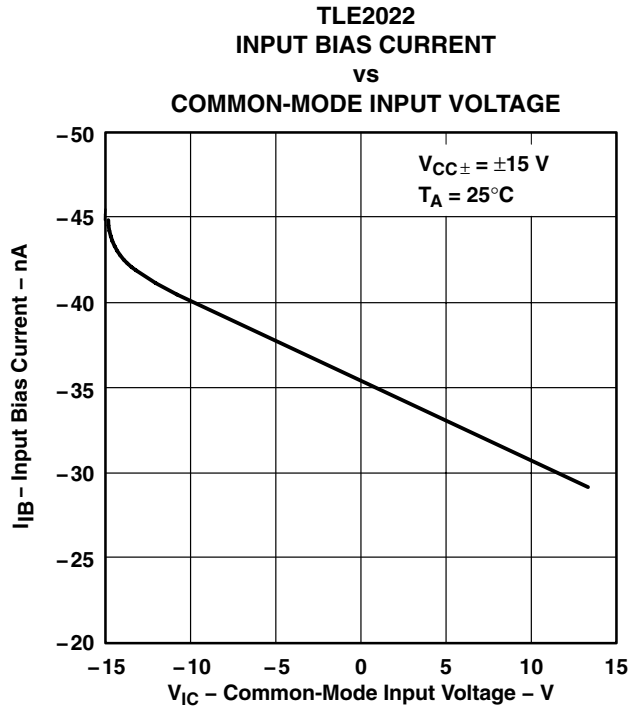


Figure 8

TYPICAL CHARACTERISTICS

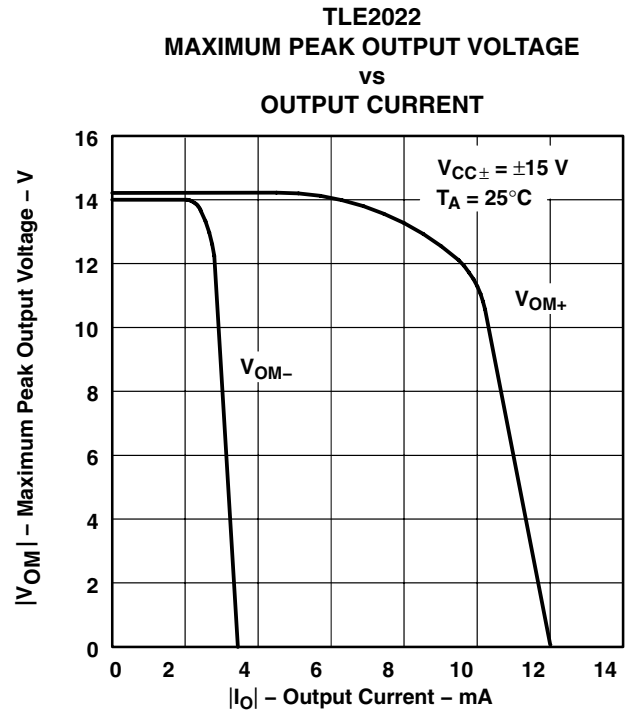
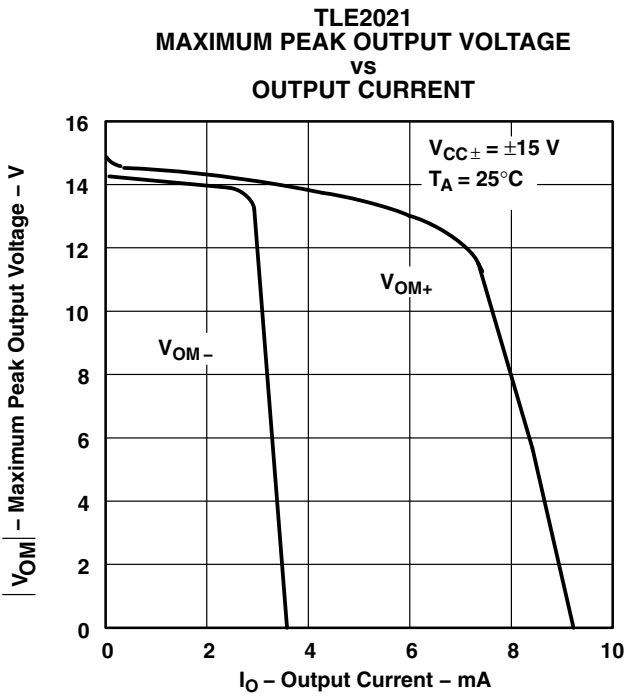
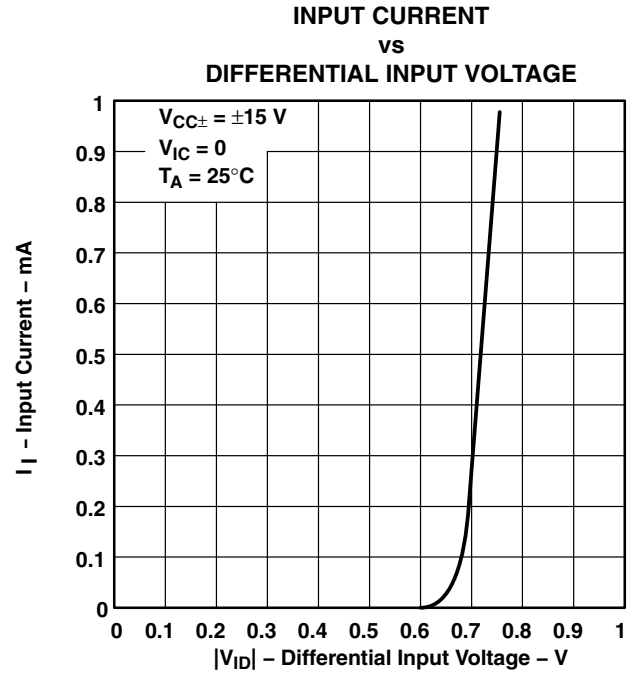
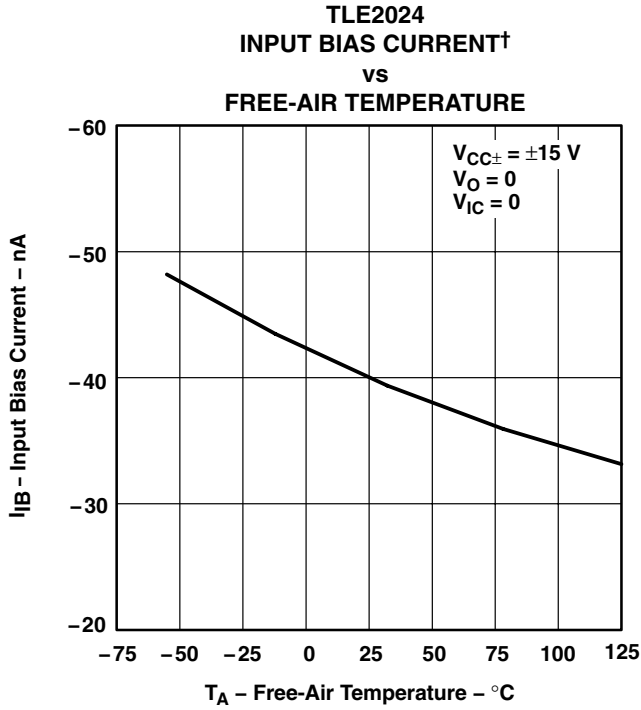


† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE202x-Q1, TLE202xA-Q1
EXCALIBUR HIGH-SPEED LOW-POWER PRECISION
OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS



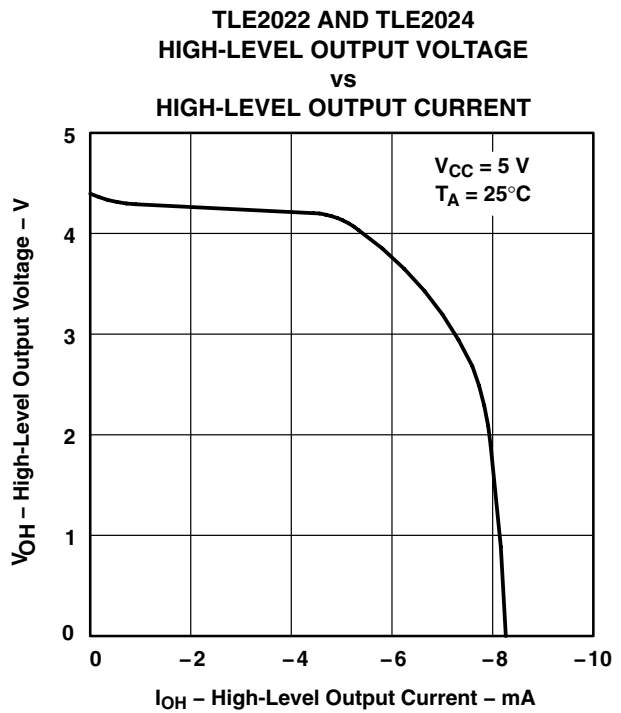
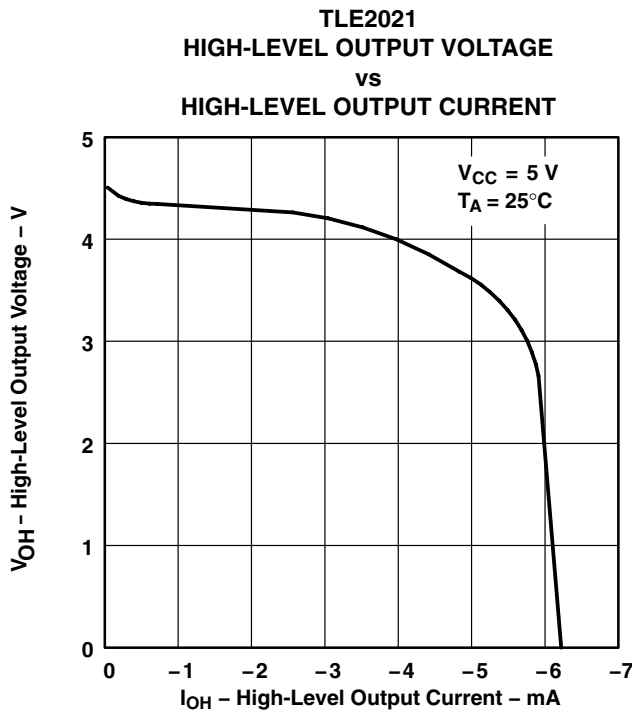
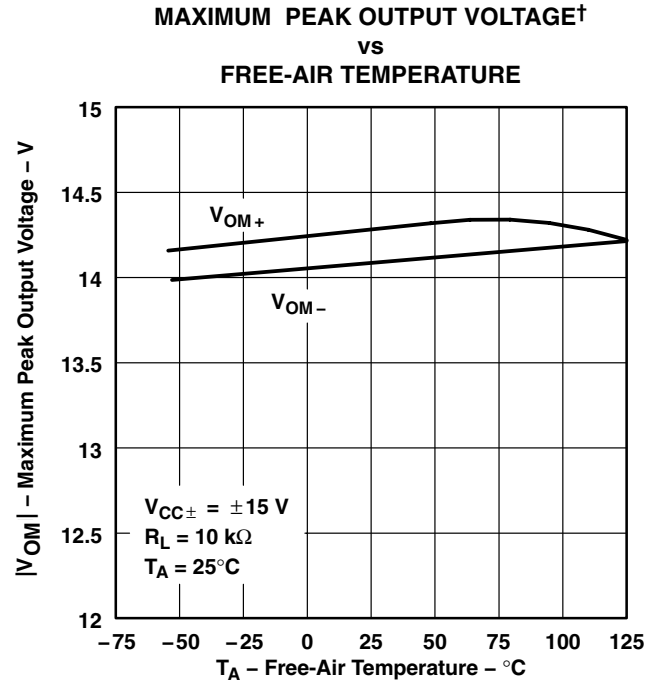
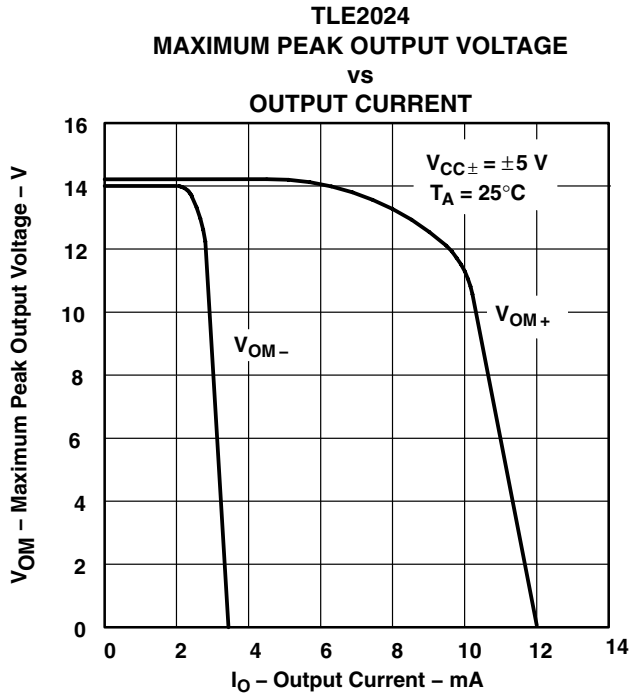
† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



TLE202x-Q1, TLE202xA-Q1
EXCALIBUR HIGH-SPEED LOW-POWER PRECISION
OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

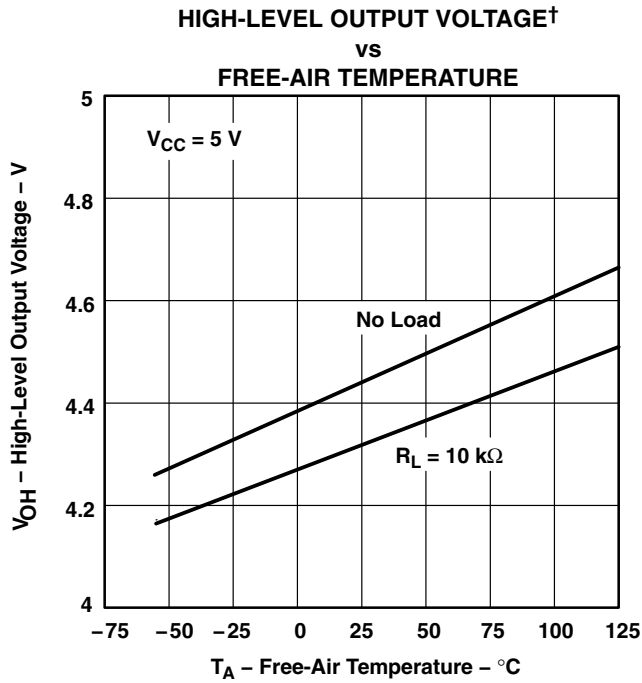


Figure 21

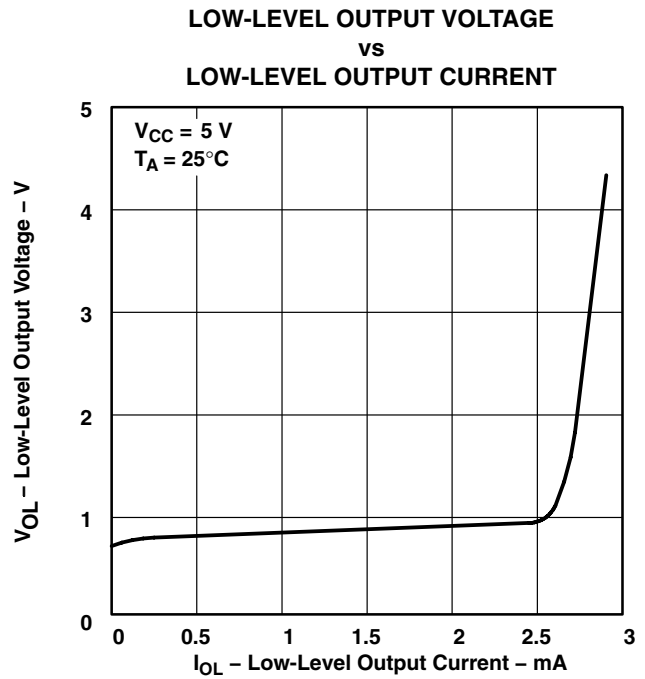


Figure 22

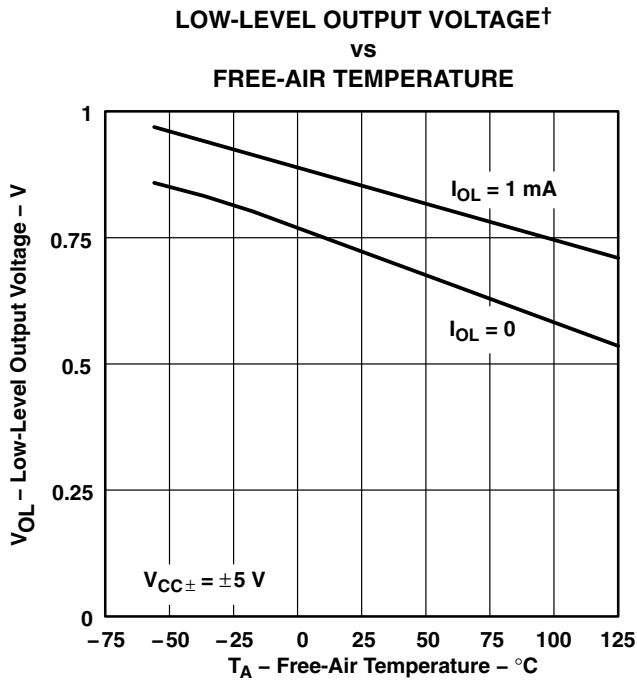


Figure 23

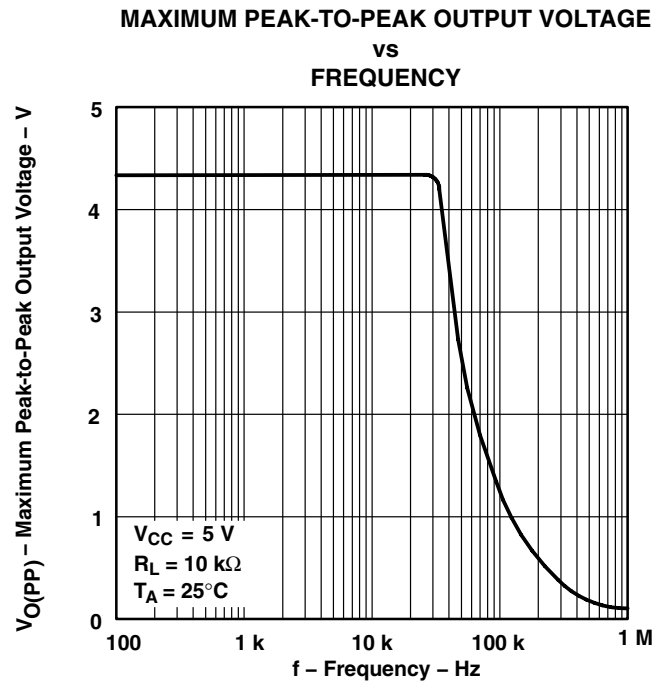


Figure 24

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE
 vs
 FREQUENCY

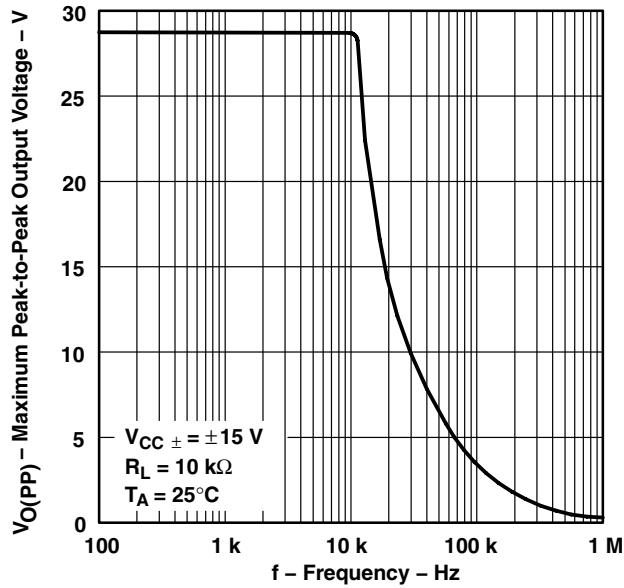


Figure 25

LARGE-SIGNAL DIFFERENTIAL VOLTAGE
 AMPLIFICATION AND PHASE SHIFT
 vs
 FREQUENCY

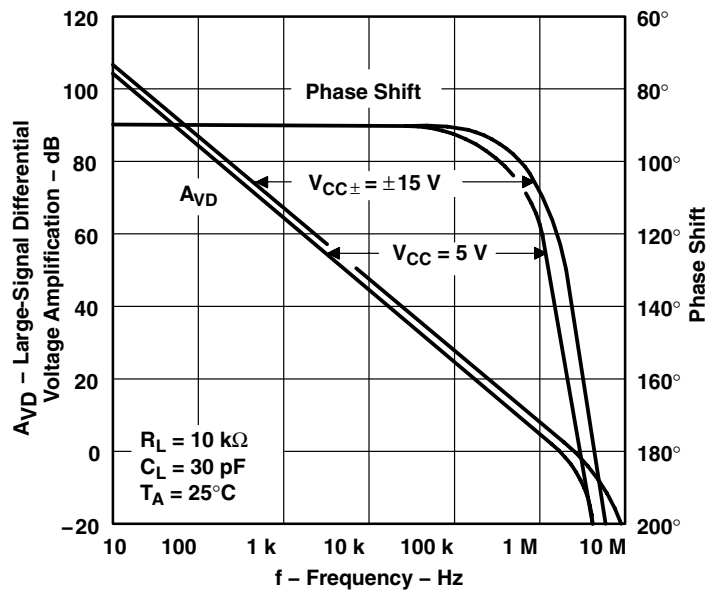


Figure 26

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

TLE2021
LARGE-SCALE DIFFERENTIAL VOLTAGE
AMPLIFICATION†
vs
FREE-AIR TEMPERATURE

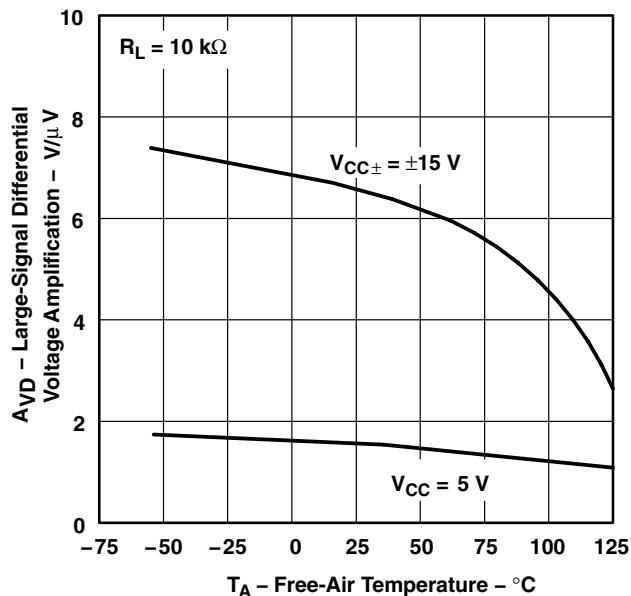


Figure 27

TLE2022
LARGE-SIGNAL DIFFERENTIAL VOLTAGE
AMPLIFICATION†
vs
FREE-AIR TEMPERATURE

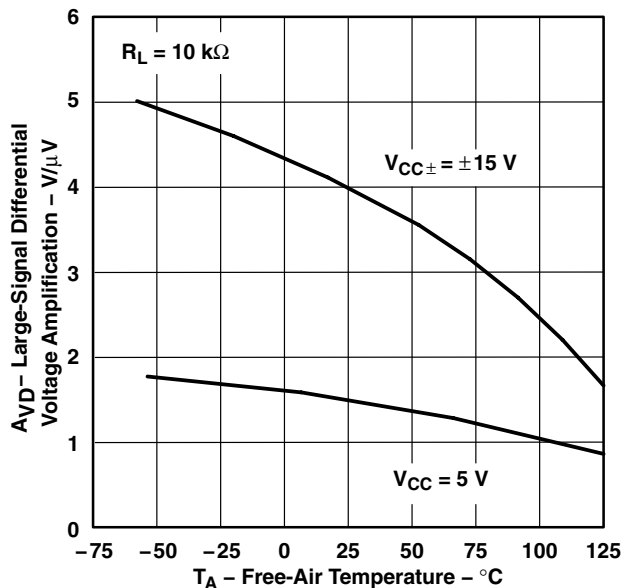


Figure 28

TLE2024
LARGE-SCALE DIFFERENTIAL VOLTAGE
AMPLIFICATION†
vs
FREE-AIR TEMPERATURE

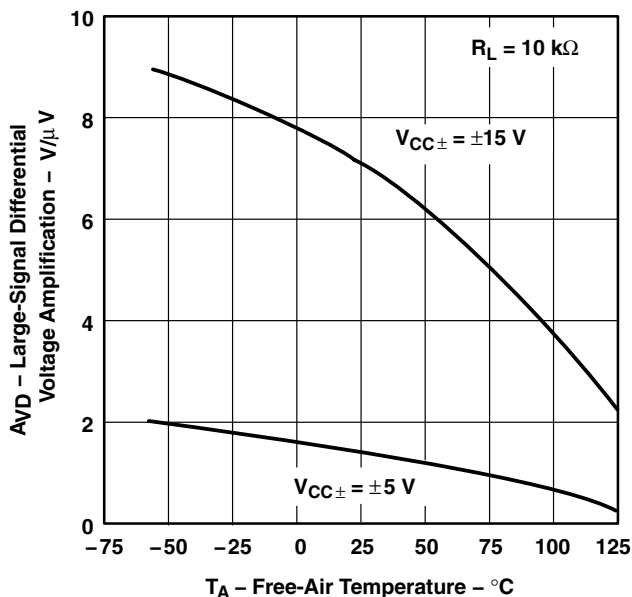


Figure 29

TLE2021
SHORT-CIRCUIT OUTPUT CURRENT
vs
SUPPLY VOLTAGE

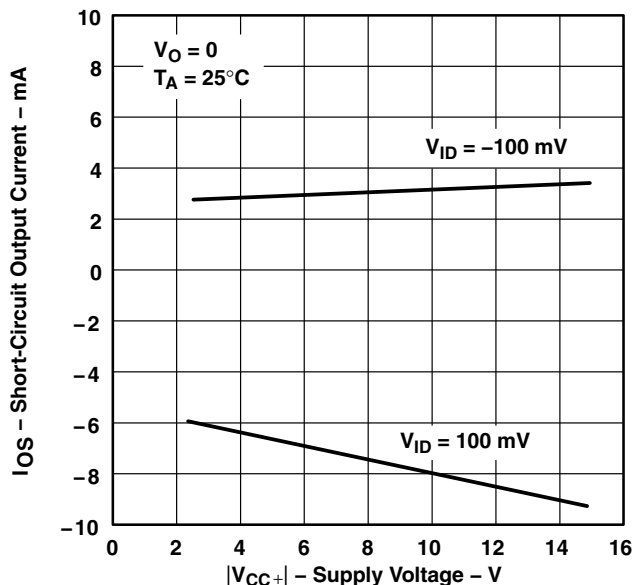


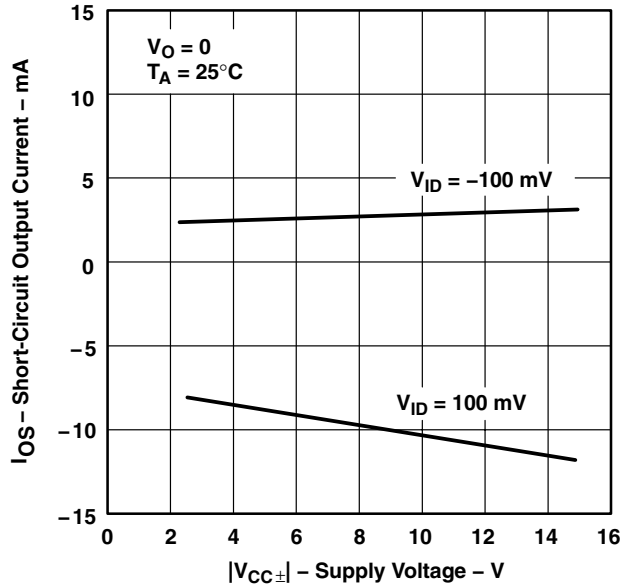
Figure 30

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

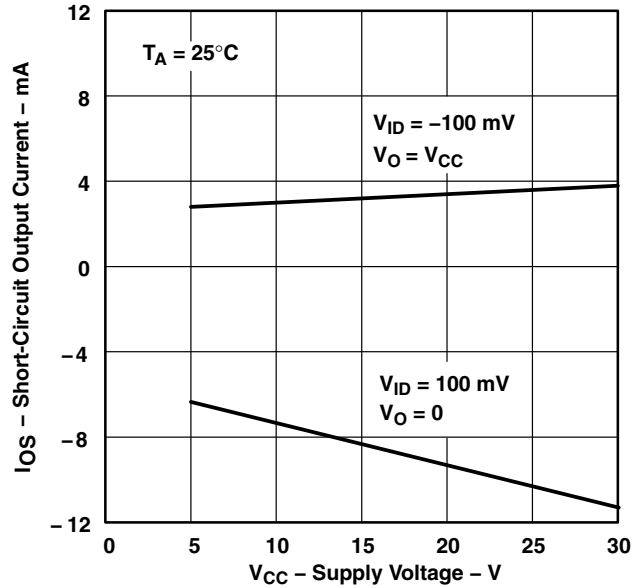


TYPICAL CHARACTERISTICS

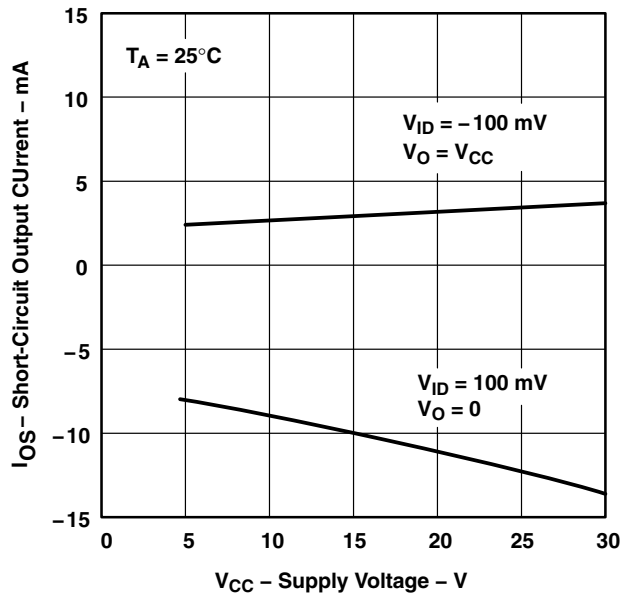
TLE2022 AND TLE2024
SHORT-CIRCUIT OUTPUT CURRENT
vs
SUPPLY VOLTAGE



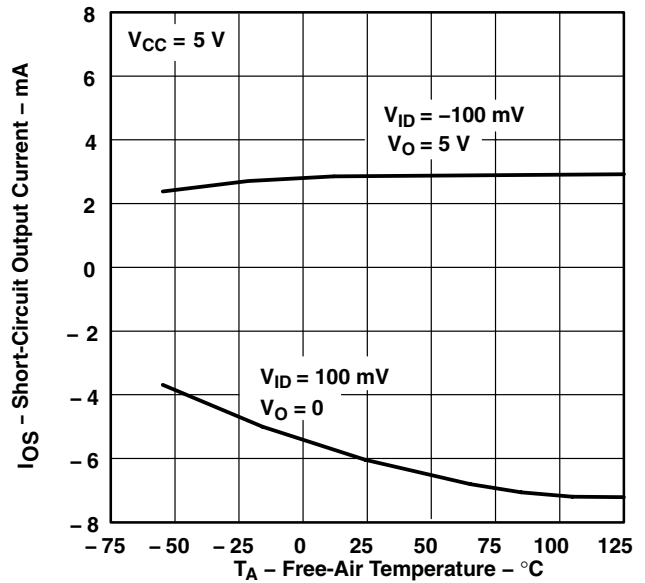
TLE2021
SHORT-CIRCUIT OUTPUT CURRENT
vs
SUPPLY VOLTAGE



TLE2022 AND TLE2024
SHORT-CIRCUIT OUTPUT CURRENT
vs
SUPPLY VOLTAGE



TLE2021
SHORT-CIRCUIT OUTPUT CURRENT†
vs
FREE-AIR TEMPERATURE



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

TLE2022 AND TLE2024
SHORT-CIRCUIT OUTPUT CURRENT†
vs
FREE-AIR TEMPERATURE

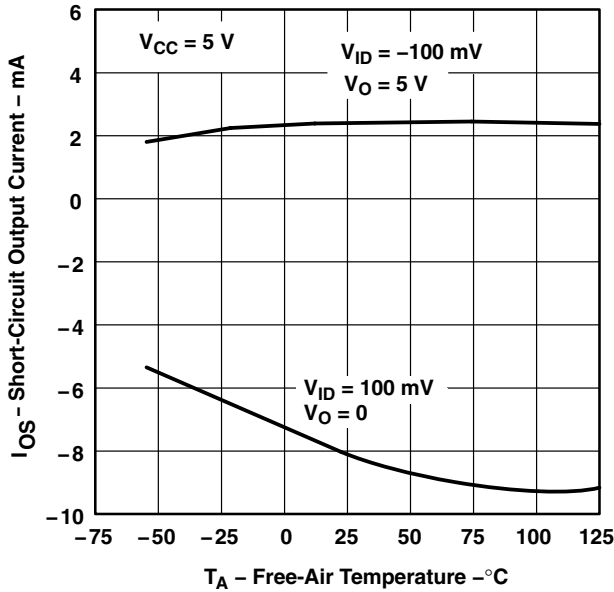


Figure 35

TLE2021
SHORT-CIRCUIT OUTPUT CURRENT†
vs
FREE-AIR TEMPERATURE

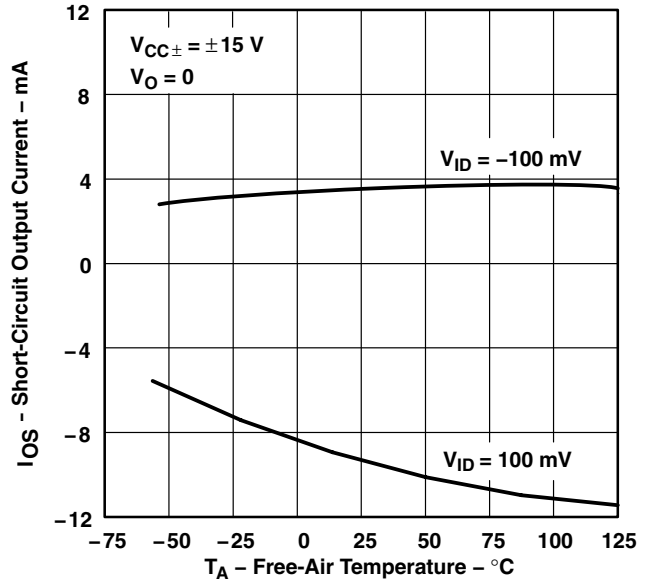


Figure 36

TLE2022 AND TLE2024
SHORT-CIRCUIT OUTPUT CURRENT†
vs
FREE-AIR TEMPERATURE

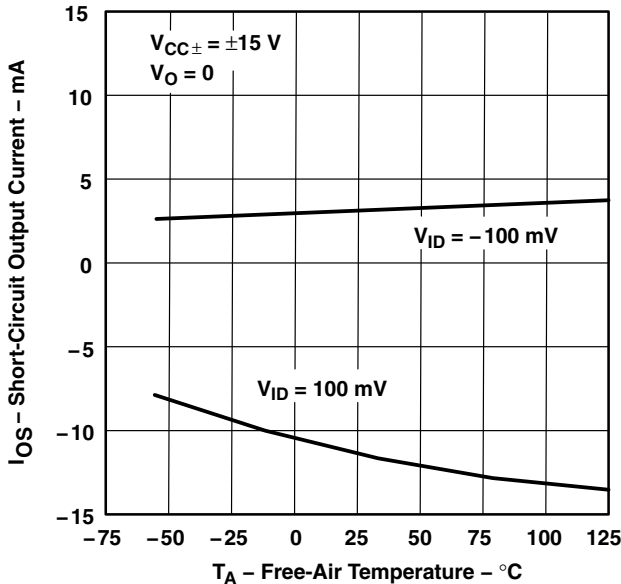


Figure 37

TLE2021
SUPPLY CURRENT
vs
SUPPLY VOLTAGE

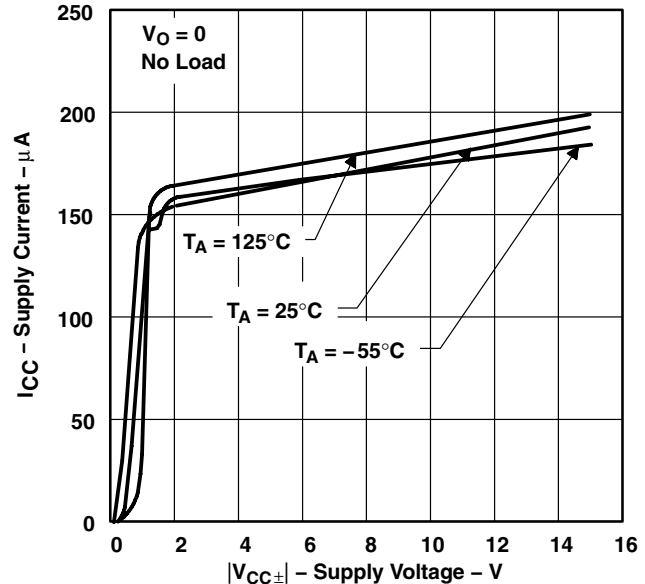
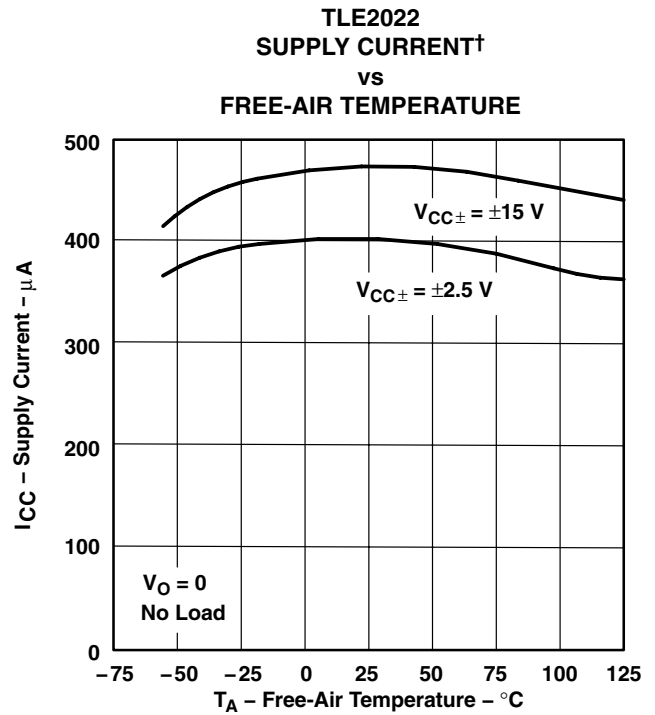
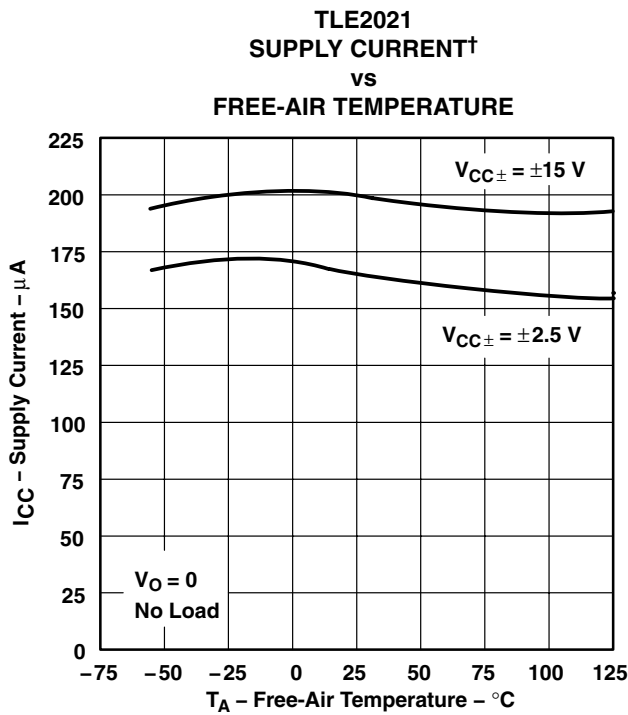
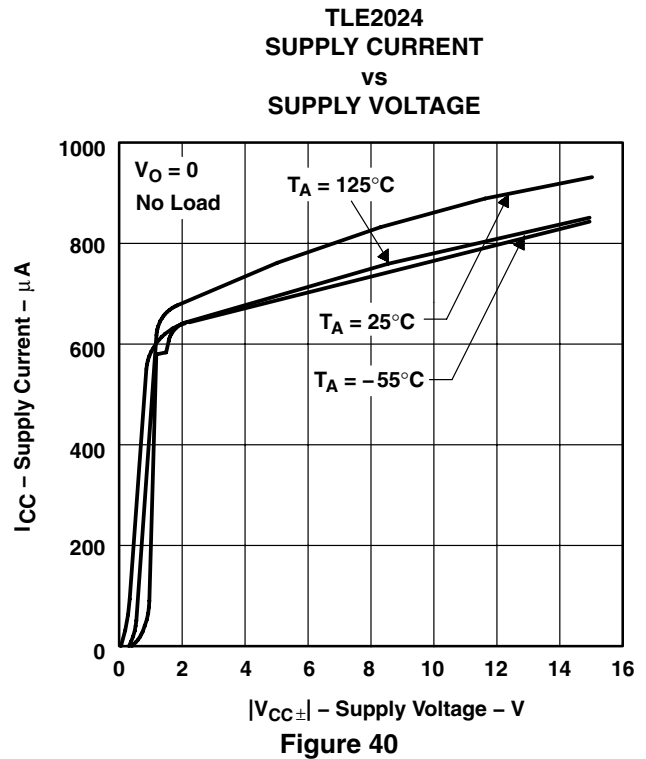
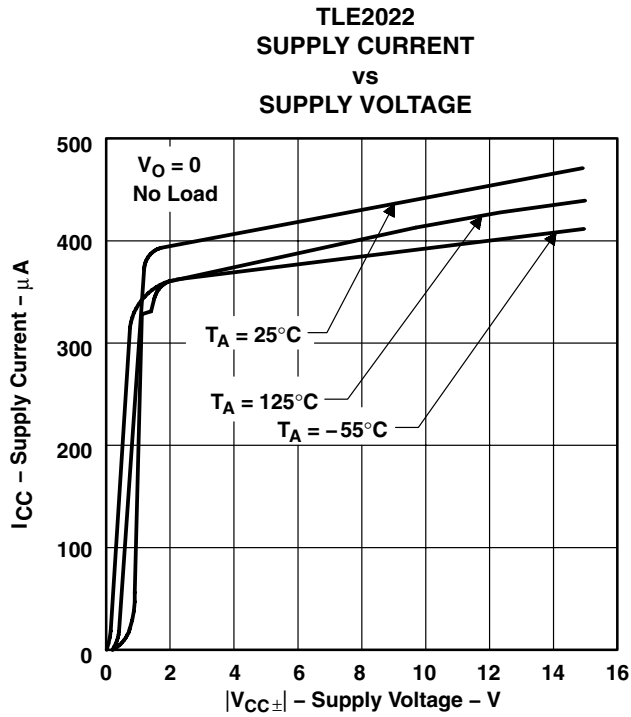


Figure 38

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

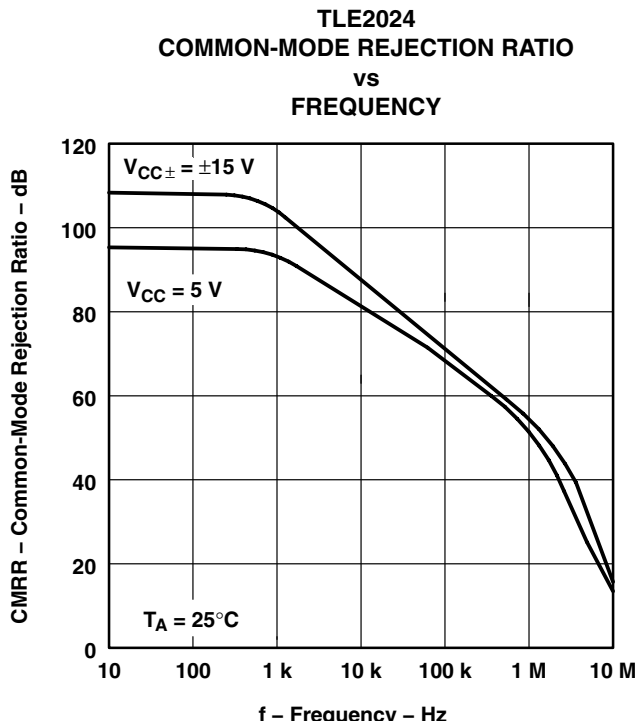
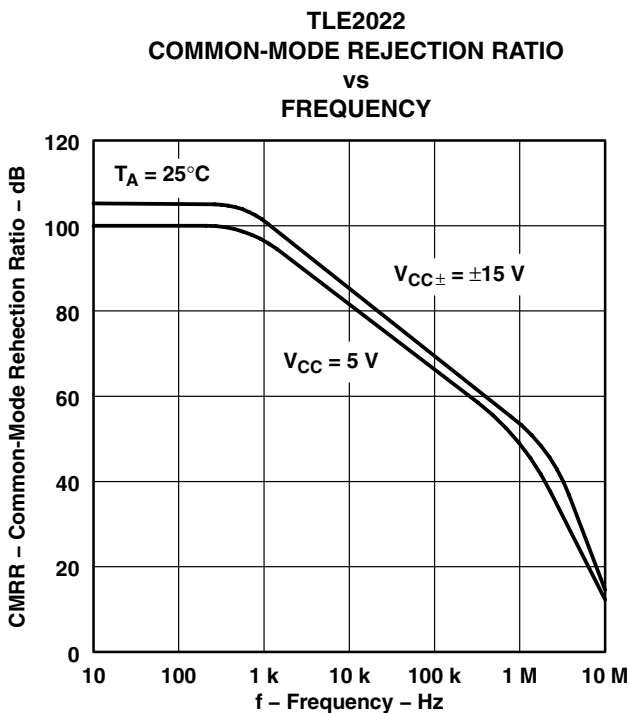
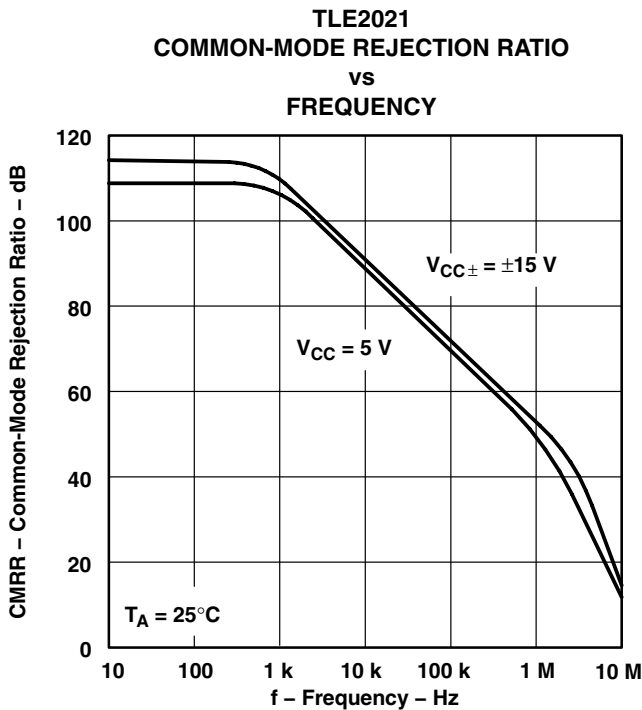
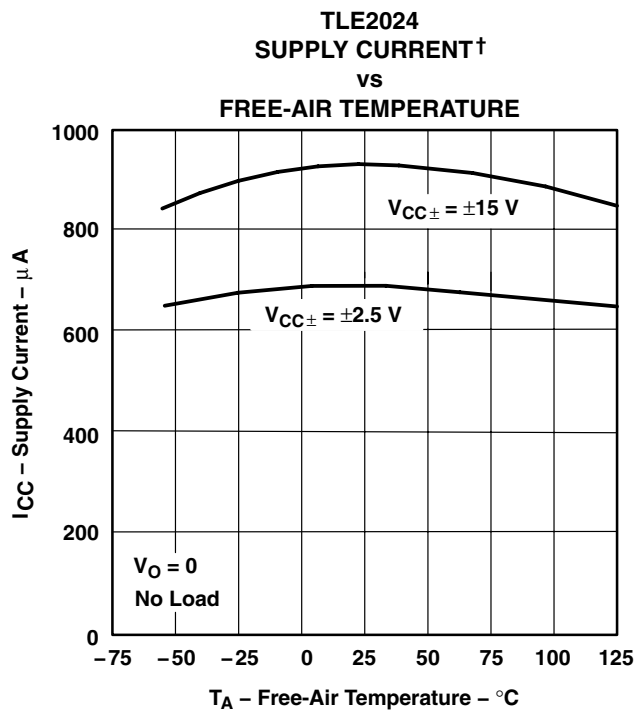


† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

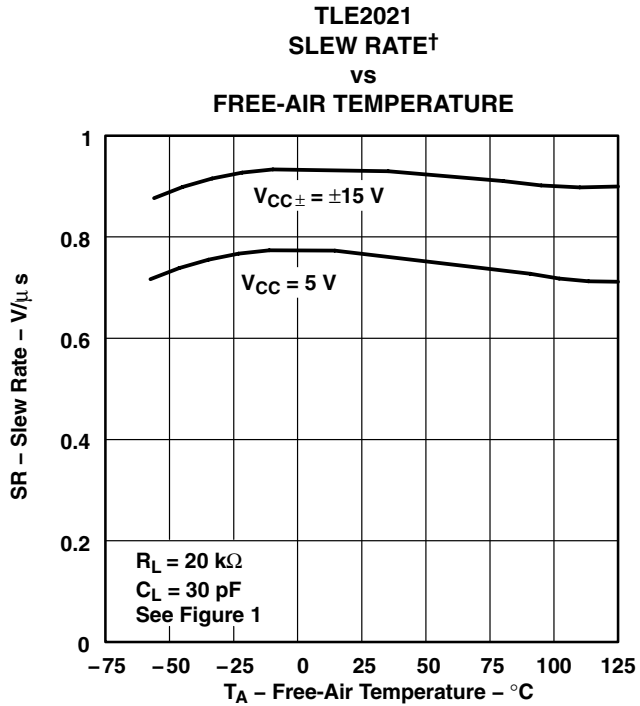


Figure 47

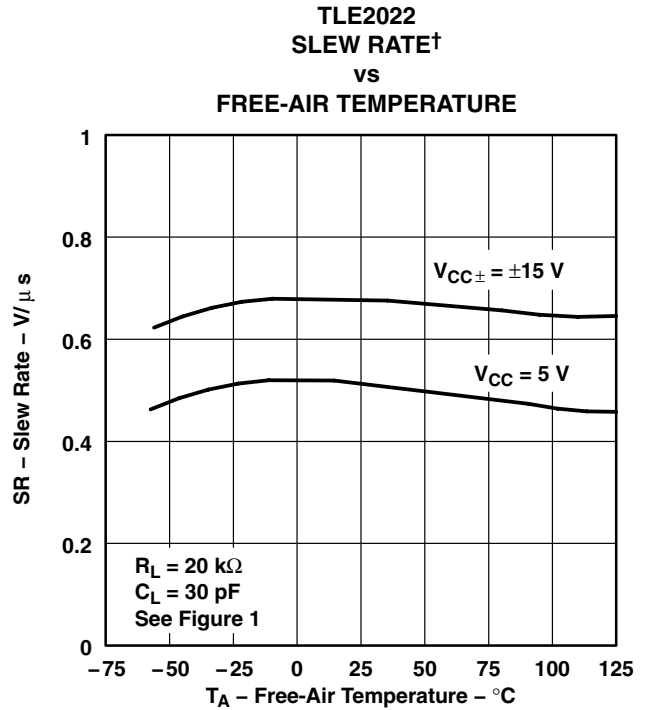


Figure 48

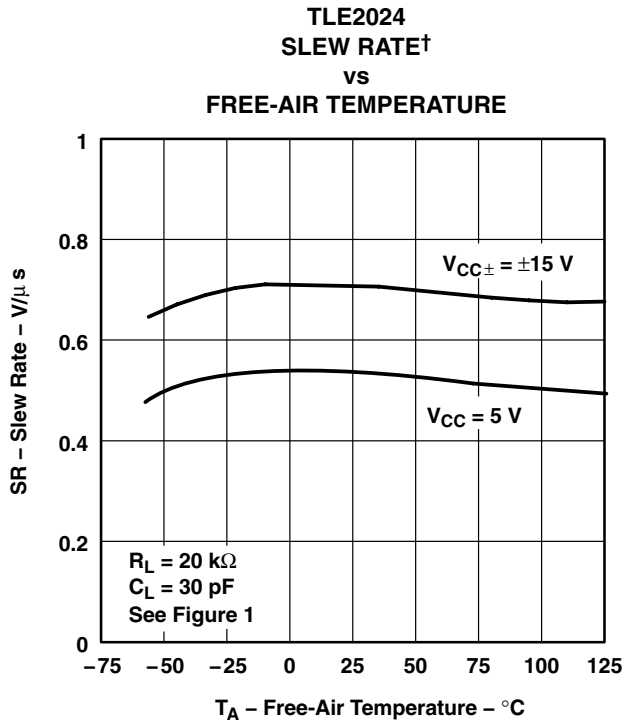


Figure 49

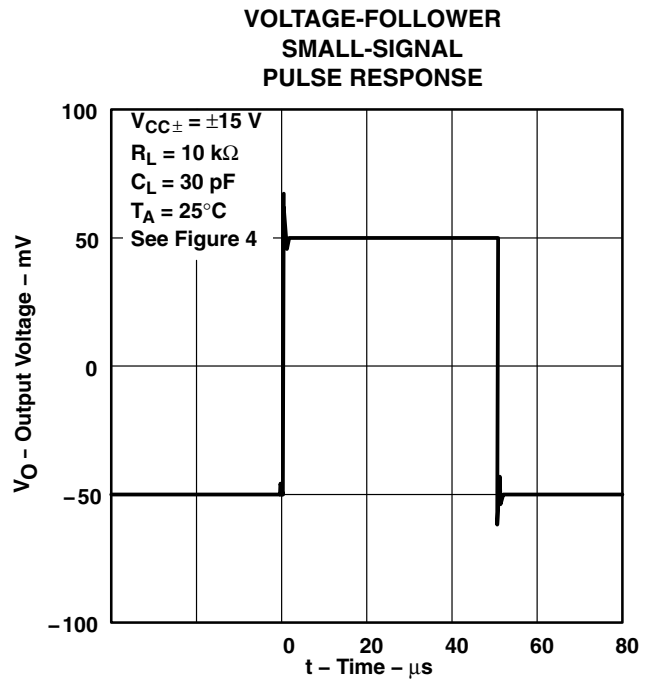


Figure 50

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

**VOLTAGE-FOLLOWER
SMALL-SIGNAL
PULSE RESPONSE**

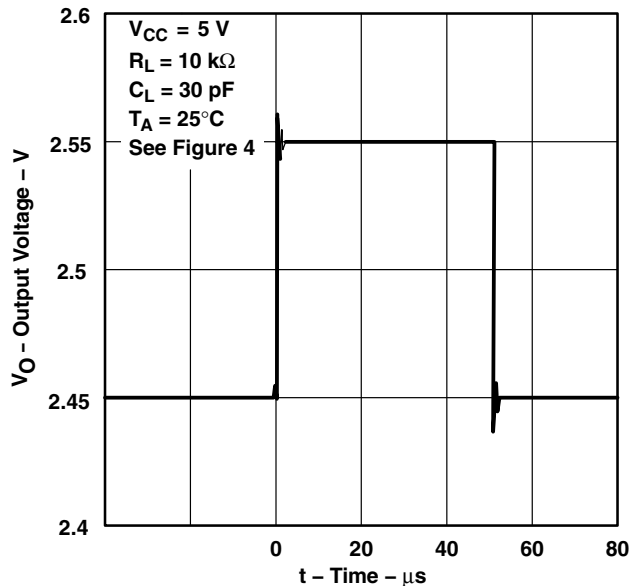


Figure 51

**TLE2021
VOLTAGE-FOLLOWER LARGE-SIGNAL
PULSE RESPONSE**

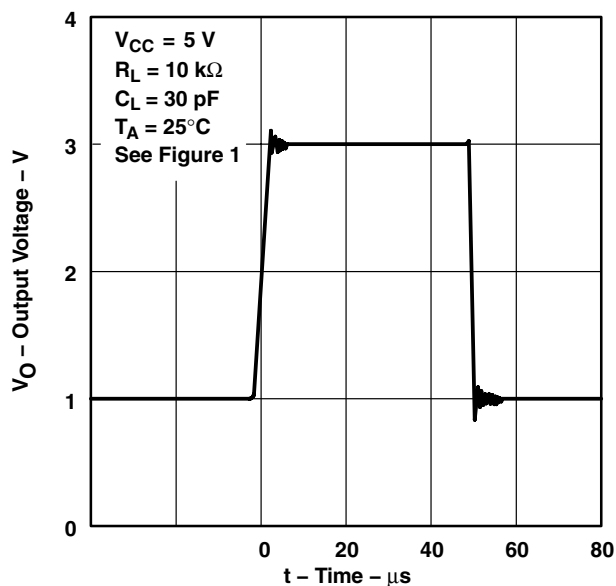


Figure 52

**TLE2022
VOLTAGE-FOLLOWER LARGE-SIGNAL
PULSE RESPONSE**

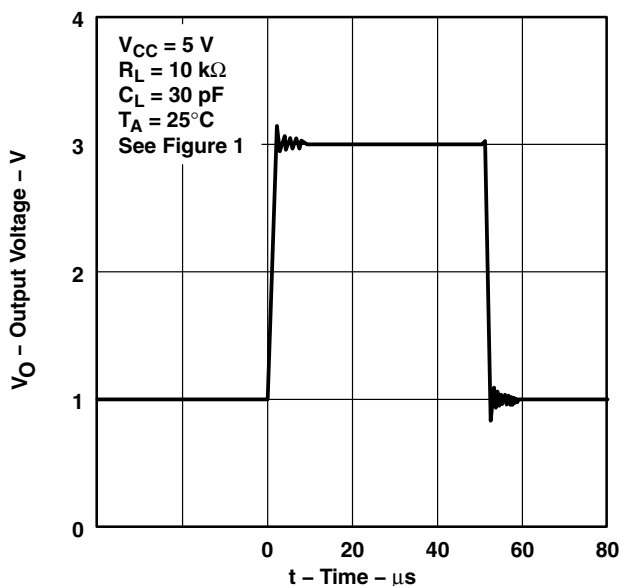


Figure 53

**TLE2024
VOLTAGE-FOLLOWER LARGE-SCALE
PULSE RESPONSE**

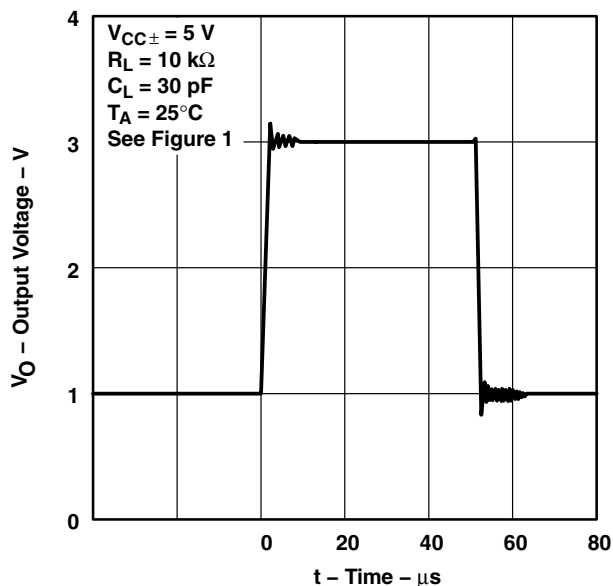
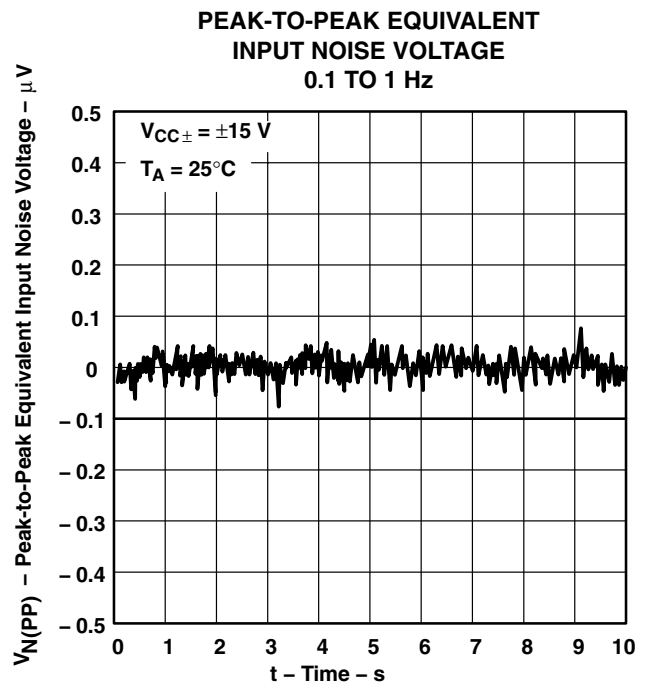
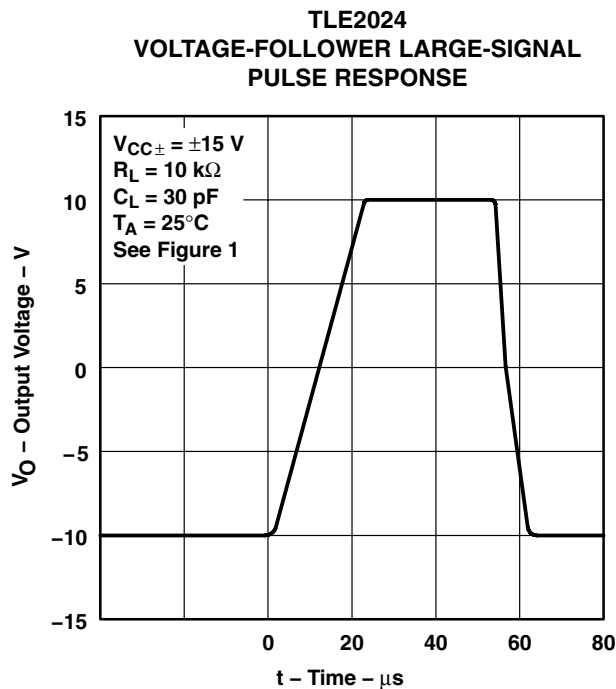
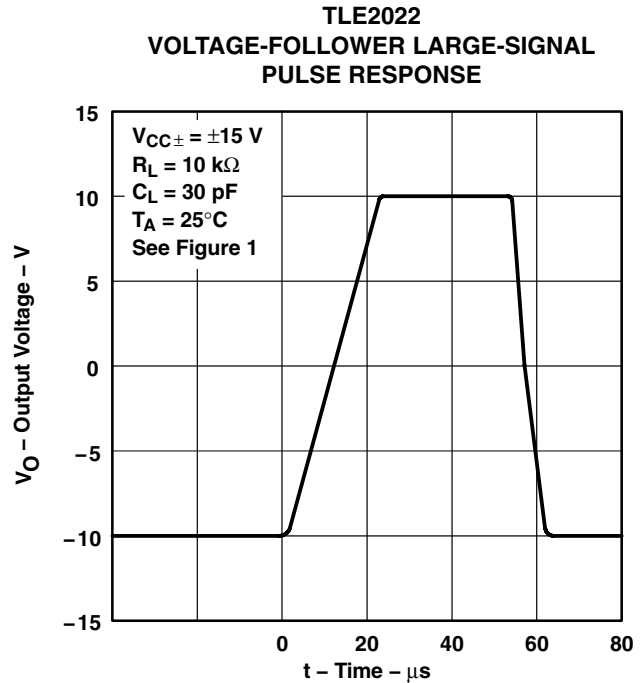
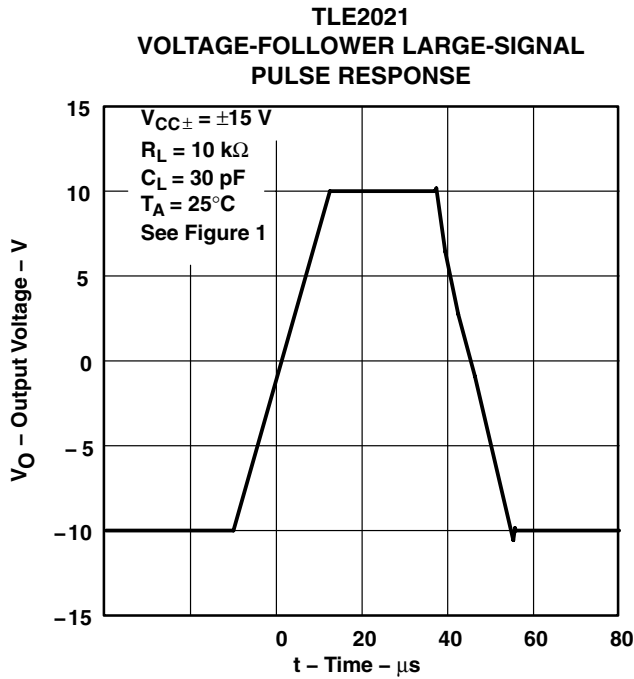


Figure 54



TYPICAL CHARACTERISTICS



TLE202x-Q1, TLE202xA-Q1
EXCALIBUR HIGH-SPEED LOW-POWER PRECISION
OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

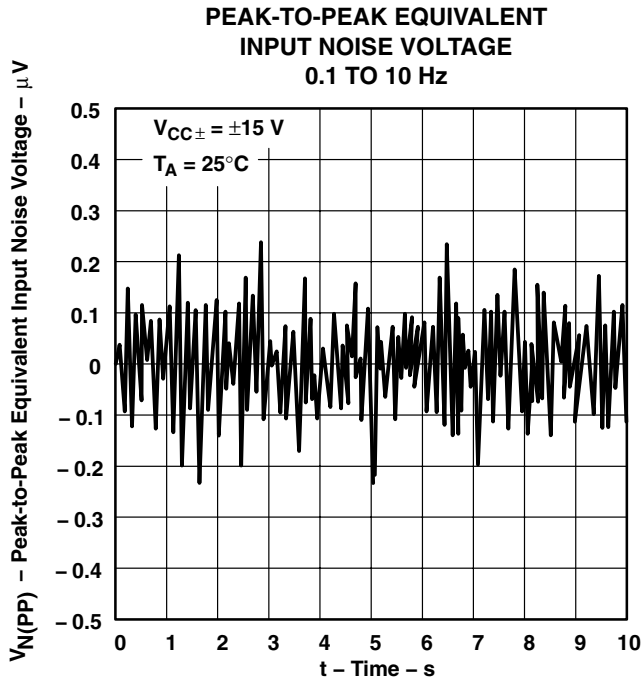


Figure 59

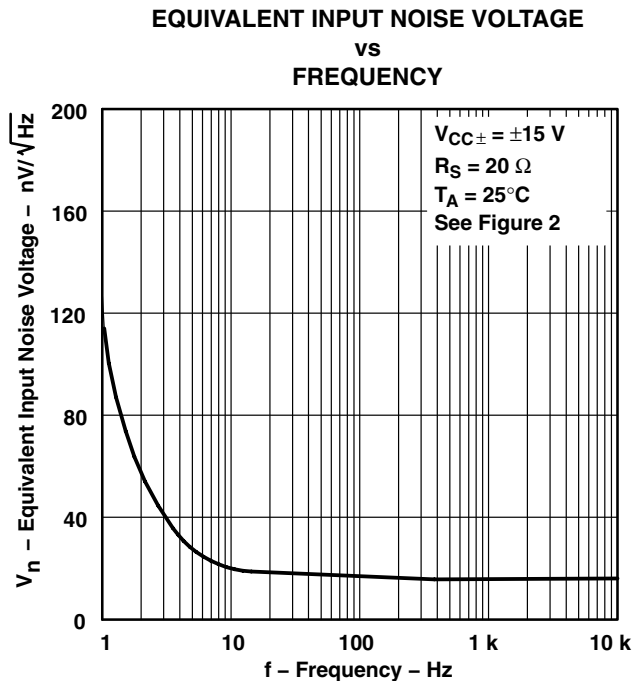


Figure 60

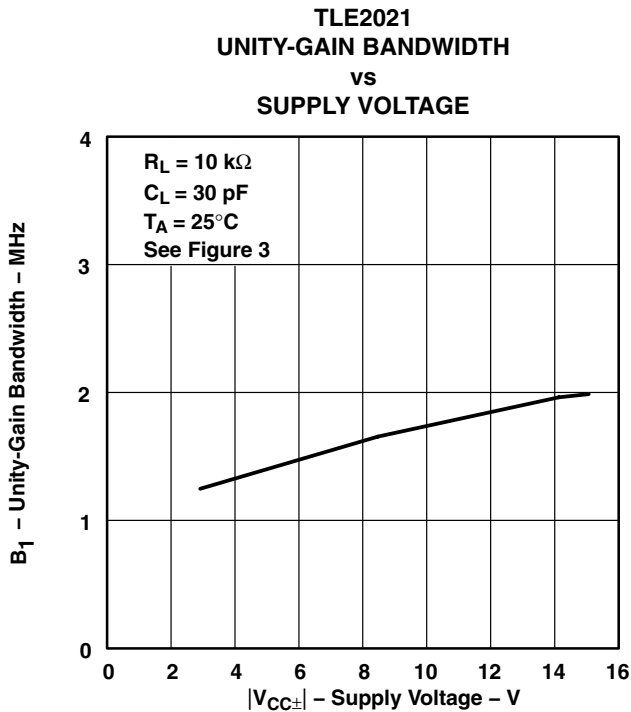


Figure 61

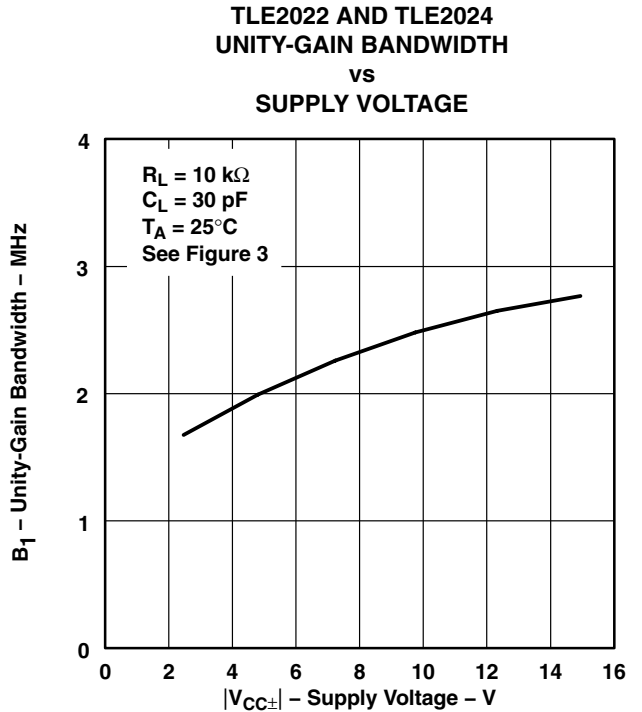
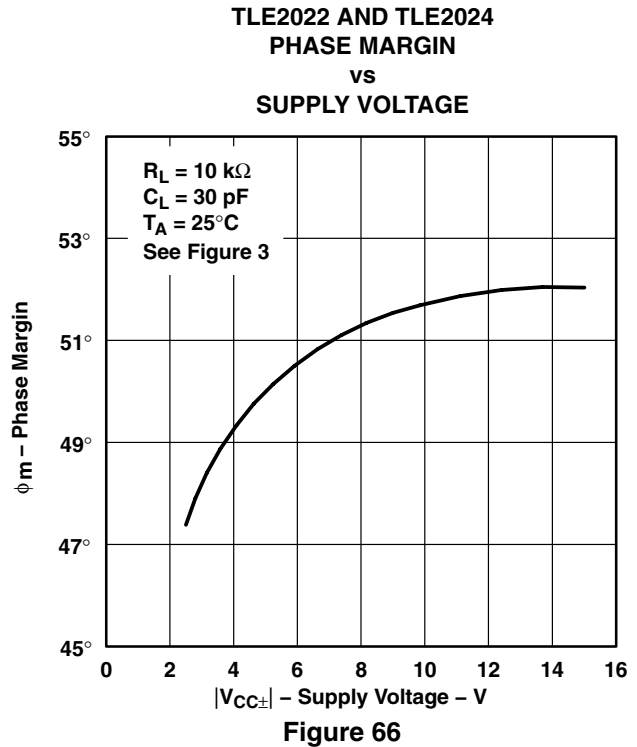
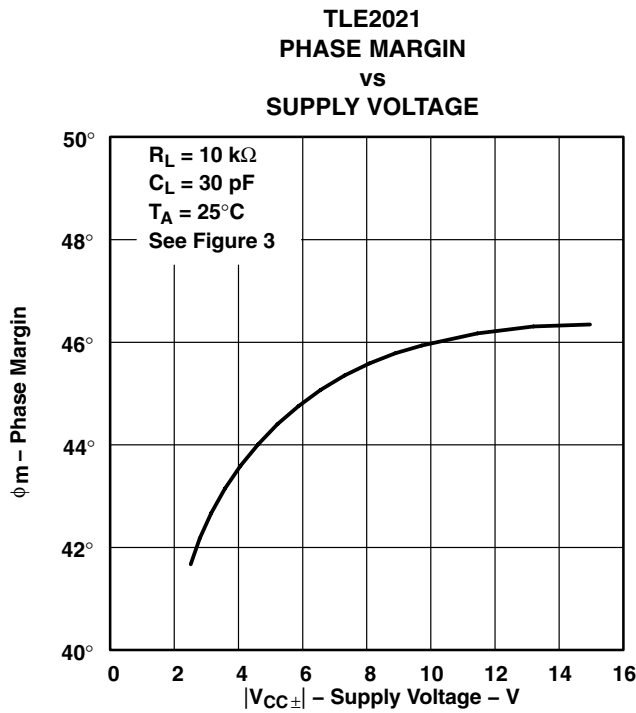
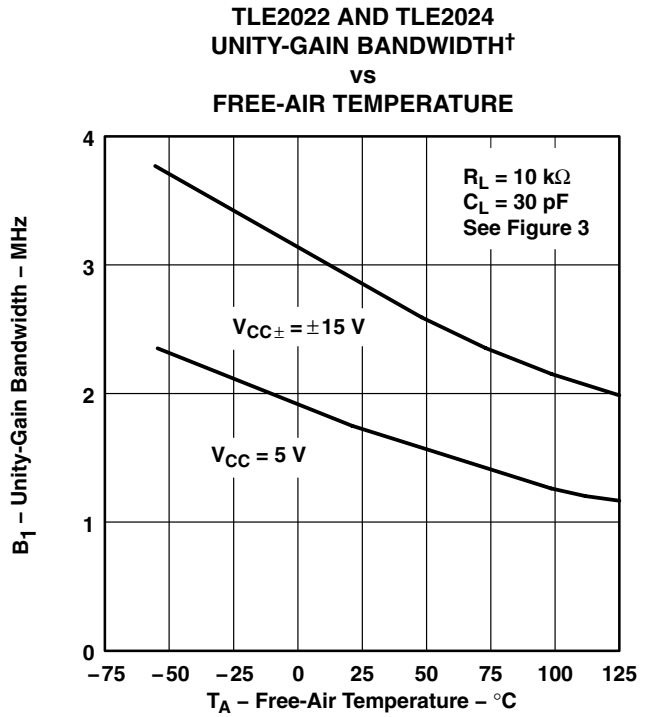
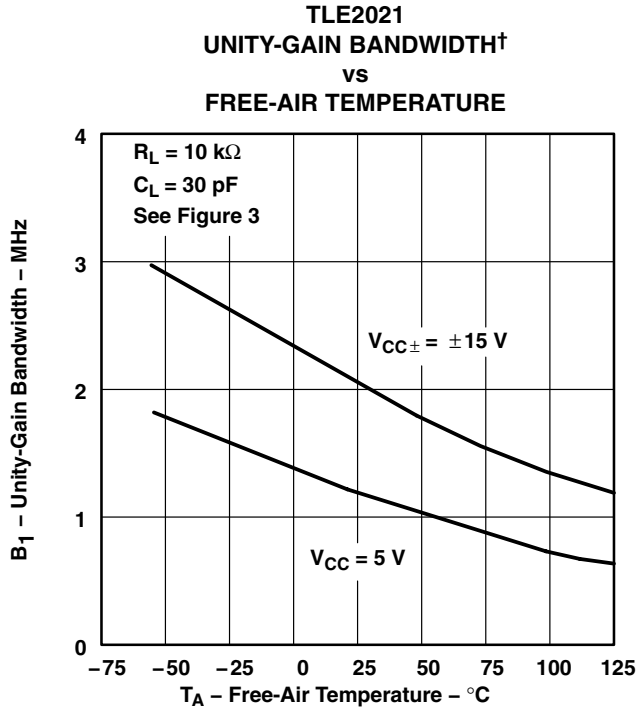


Figure 62



TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

**TLE2021
PHASE MARGIN
vs
LOAD CAPACITANCE**

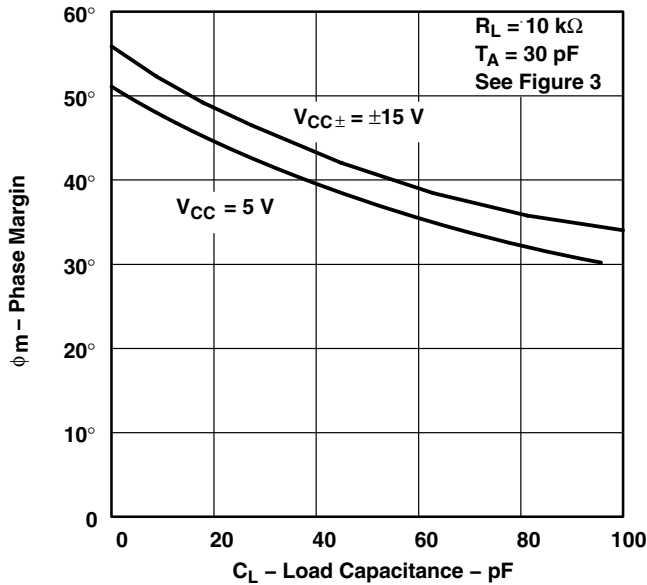


Figure 67

**TLE2022 AND TLE2024
PHASE MARGIN
vs
LOAD CAPACITANCE**

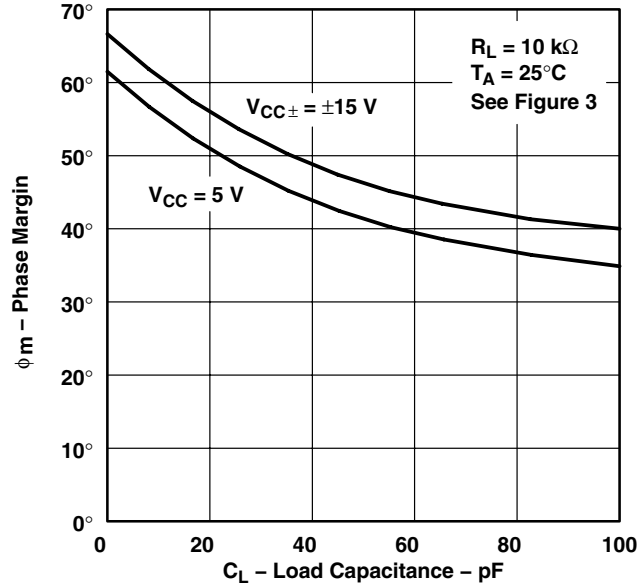


Figure 68

**TLE2021
PHASE MARGIN†
vs
FREE-AIR TEMPERATURE**

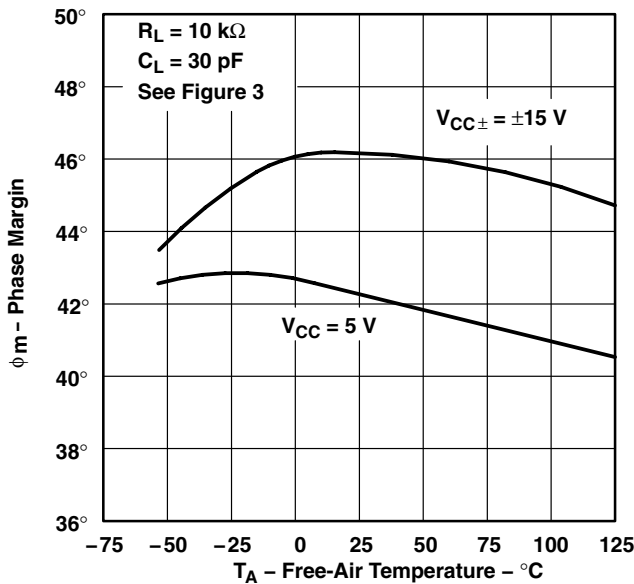


Figure 69

**TLE2022 AND TLE2024
PHASE MARGIN†
vs
FREE-AIR TEMPERATURE**

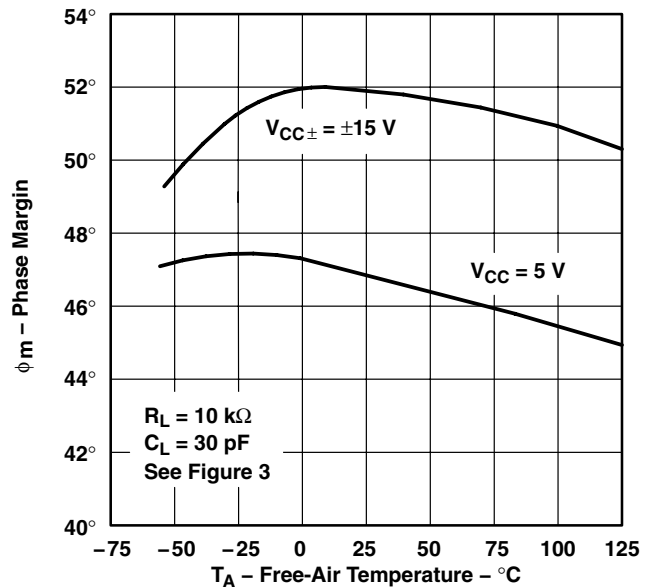


Figure 70

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

APPLICATION INFORMATION

voltage-follower applications

The TLE202x circuitry includes input-protection diodes to limit the voltage across the input transistors; however, no provision is made in the circuit to limit the current if these diodes are forward biased. This condition can occur when the device is operated in the voltage-follower configuration and driven with a fast, large-signal pulse. It is recommended that a feedback resistor be used to limit the current to a maximum of 1 mA to prevent degradation of the device. This feedback resistor forms a pole with the input capacitance of the device. For feedback resistor values greater than 10 kΩ, this pole degrades the amplifier phase margin. This problem can be alleviated by adding a capacitor (20 pF to 50 pF) in parallel with the feedback resistor (see Figure 71).

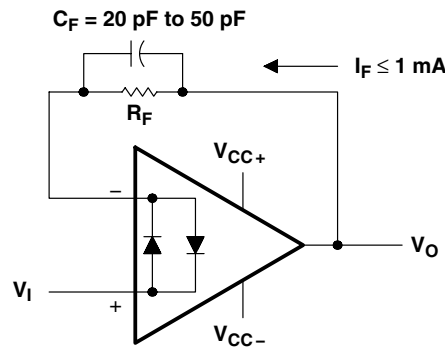


Figure 71. Voltage Follower

Input offset voltage nulling

The TLE202x series offers external null pins that further reduce the input offset voltage. The circuit in Figure 72 can be connected as shown if this feature is desired. When external nulling is not needed, the null pins may be left disconnected.

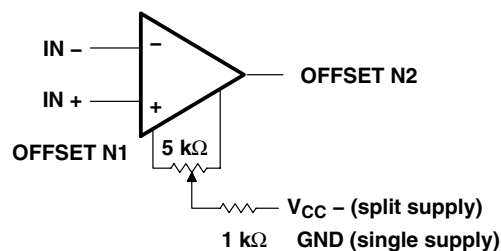


Figure 72. Input Offset Voltage Null Circuit

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*[™], the model generation software used with Microsim *PSpice*[™]. The Boyle macromodel (see Note 5) and subcircuit in Figure 73, Figure 74, and Figure 75 were generated using the TLE202x typical electrical and operating characteristics at 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 5: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

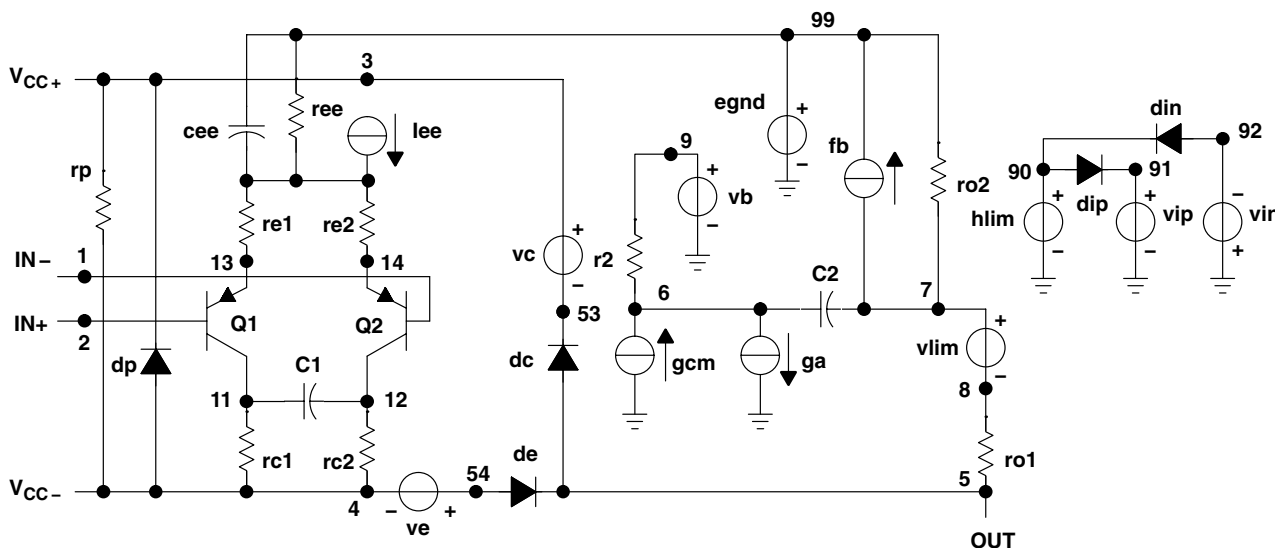


Figure 73. Boyle Subcircuit

PSpice and *Parts* are trademarks of MicroSim Corporation.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

TLE202x-Q1, TLE202xA-Q1 EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

SGLS199B – JANUARY 2004 – REVISED APRIL 2008

```
.SUBCKT TLE2021 1 2 3 4 5
*
c1 11 12 6.244E-12
c2 6 7 13.4E-12
c3 87 0 10.64E-9
cpsr 85 86 15.9E-9
dcm+ 81 82 dx
dcm- 83 81 dx
dc 5 53 dx
de 54 5 dx
dlp 90 91 dx
dln 92 90 dx
dp 4 3 dx
ecmr 84 99 (2 99) 1
egnd 99 0 poly(2) (3,0) (4,0) 0 .5 .5
epsr 85 0 poly(1) (3,4) -60E-6 2.0E-6
ense 89 2 poly(1) (88,0) 120E-6 1
fb 7 99 poly(6) vb vc ve vlp vln vpsr 0 547.3E6
+ -50E7 50E7 50E7 -50E7 547E6
ga 6 0 11 12 188.5E-6
gcm 0 6 10 99 335.2E-12
gpsr 85 86 (85,86) 100E-6
grc1 4 11 (4,11) 1.885E-4
grc2 4 12 (4,12) 1.885E-4
gre1 13 10 (13,10) 6.82E-4
gre2 14 10 (14,10) 6.82E-4
hlim 90 0 vlim 1k

hcmr 80 1 poly(2) vcm+ vcm- 0 1E2 1E2
irp 3 4 185E-6
iee 3 10 dc 15.67E-6
iio 2 0 2E-9
i1 88 0 1E-21
q1 11 89 13 qx
q2 12 80 14 qx
R2 6 9 100.0E3
rcm 84 81 1K
ree 10 99 14.76E6
rn1 87 0 2.55E8
rn2 87 88 11.67E3
ro1 8 5 62
ro2 7 99 63
vcm+ 82 99 13.3
vcm- 83 99 -14.6
vb 9 0 dc 0
vc 3 53 dc 1.300
ve 54 4 dc 1.500
vlim 7 8 dc 0
vlp 91 0 dc 3.600
vln 0 92 dc 3.600
vpsr 0 86 dc 0
.model dx d(is=800.0E-18)
.model qx pnp(is=800.0E-18 bf=270)
.ends
```

Figure 74. Boyle Macromodel for the TLE2021

```
.SUBCKT TLE2022 1 2 3 4 5
*
c1 11 12 6.814E-12
c2 6 7 20.00E-12
dc 5 53 dx
de 54 5 dx
dlp 90 91 dx
dln 92 90 dx
dp 4 3 dx
egnd 99 0 poly(2) (3,0) (4,0) 0 .5 .5
fb 7 99 poly(5) vb vc ve vlp vln 0
+ 45.47E6 -50E6 50E6 50E6 -50E6
ga 6 0 11 12 377.9E-6
gcm 0 6 10 99 7.84E-10
iee 3 10 DC 18.07E-6
hlim 90 0 vlim 1k
q1 11 2 13 qx
q2 12 1 14 qx
r2 6 9 100.0E3

rc1 4 11 2.842E3
rc2 4 12 2.842E3
ge1 13 10 (10,13) 31.299E-3
ge2 14 10 (10,14) 31.299E-3
ree 10 99 11.07E6
ro1 8 5 250
ro2 7 99 250
rp 3 4 137.2E3
vb 9 0 dc 0
vc 3 53 dc 1.300
ve 54 4 dc 1.500
vlim 7 8 dc 0
vlp 91 0 dc 3
vln 0 92 dc 3
.model dx d(is=800.0E-18)
.model qx pnp(is=800.0E-18 bf=257.1)
.ends
```

Figure 75. Boyle Macromodel for the TLE2022



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLE2021AQDRG4Q1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2021AQ	Samples
TLE2021AQDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2021AQ	Samples
TLE2021QDRG4Q1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2021Q1	Samples
TLE2021QDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2021Q1	Samples
TLE2022AQDRG4Q1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2022AQ	Samples
TLE2022QDRG4Q1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2022Q1	Samples
TLE2022QDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2022Q1	Samples
TLE2024AQDWRG4Q1	ACTIVE	SOIC	DW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2024AQ1	Samples
TLE2024QDWRG4Q1	ACTIVE	SOIC	DW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2024Q1	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "--" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TLE2021-Q1, TLE2021A-Q1, TLE2022-Q1, TLE2022A-Q1, TLE2024-Q1, TLE2024A-Q1 :

- Catalog: [TLE2021](#), [TLE2021A](#), [TLE2022](#), [TLE2022A](#), [TLE2024](#), [TLE2024A](#)
- Enhanced Product: [TLE2021-EP](#), [TLE2021A-EP](#), [TLE2022-EP](#), [TLE2022A-EP](#), [TLE2024-EP](#), [TLE2024A-EP](#)
- Military: [TLE2021M](#), [TLE2021AM](#), [TLE2022M](#), [TLE2022AM](#), [TLE2024M](#), [TLE2024AM](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications
- Military - QML certified for Military and Defense Applications

GENERIC PACKAGE VIEW

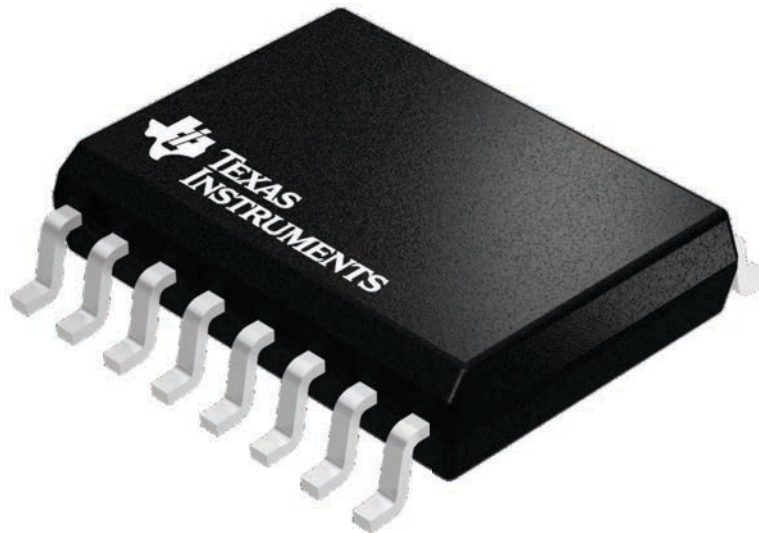
DW 16

SOIC - 2.65 mm max height

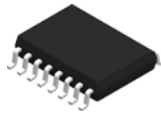
7.5 x 10.3, 1.27 mm pitch

SMALL OUTLINE INTEGRATED CIRCUIT

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4224780/A

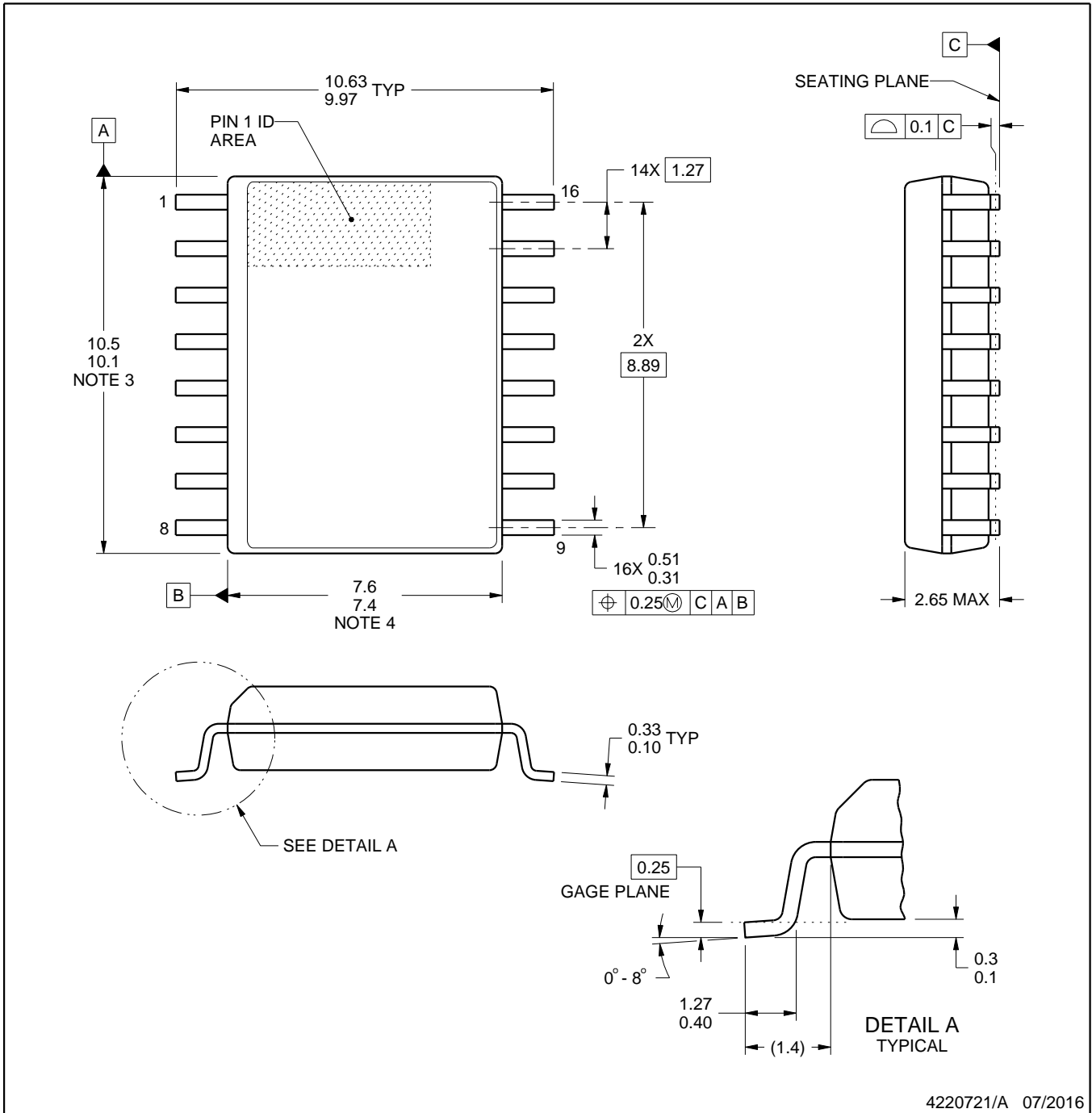


DW0016A

PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



4220721/A 07/2016

NOTES:

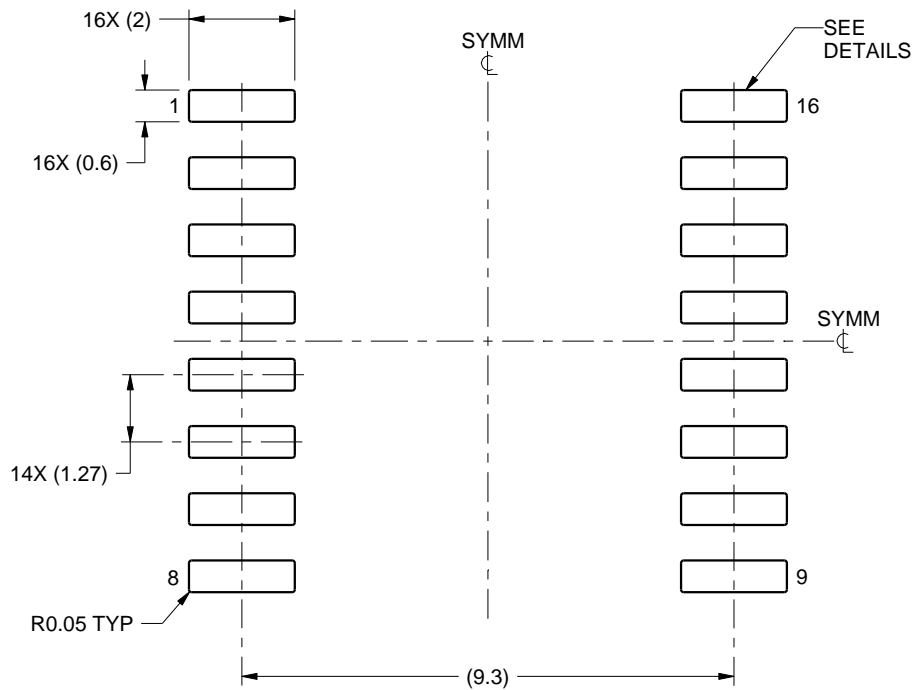
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

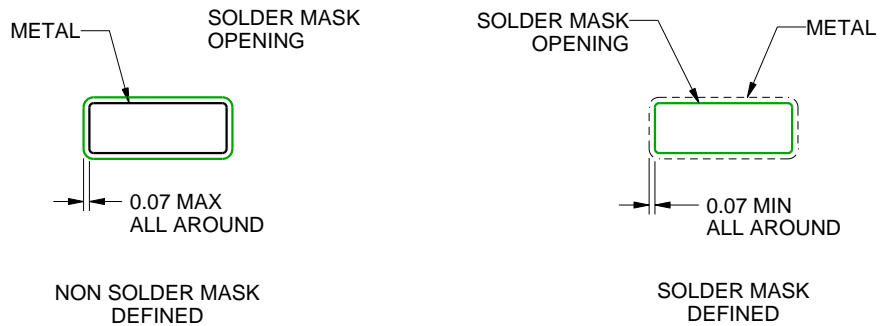
DW0016A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:7X



SOLDER MASK DETAILS

4220721/A 07/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

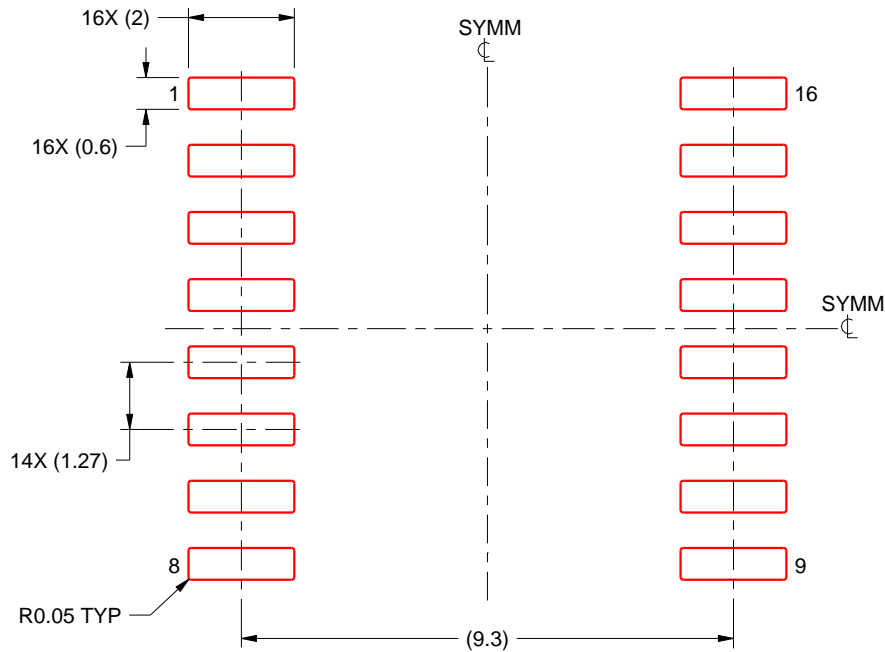
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0016A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:7X

4220721/A 07/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

- Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed $.006$ [0.15] per side.
- This dimension does not include interlead flash.
- Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
 EXPOSED METAL SHOWN
 SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2020, Texas Instruments Incorporated